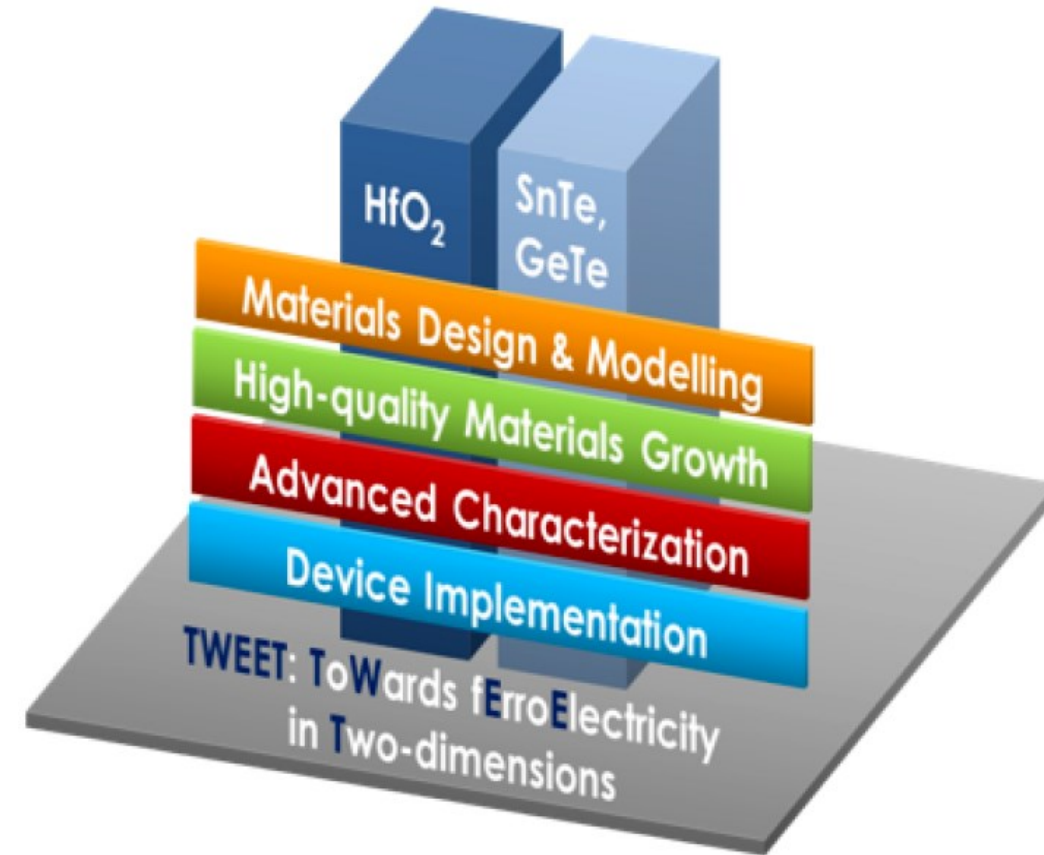


# TWEET final Talk

## Second harmonic Generation on 2D ferroelectrics

**Rohit Kumar**

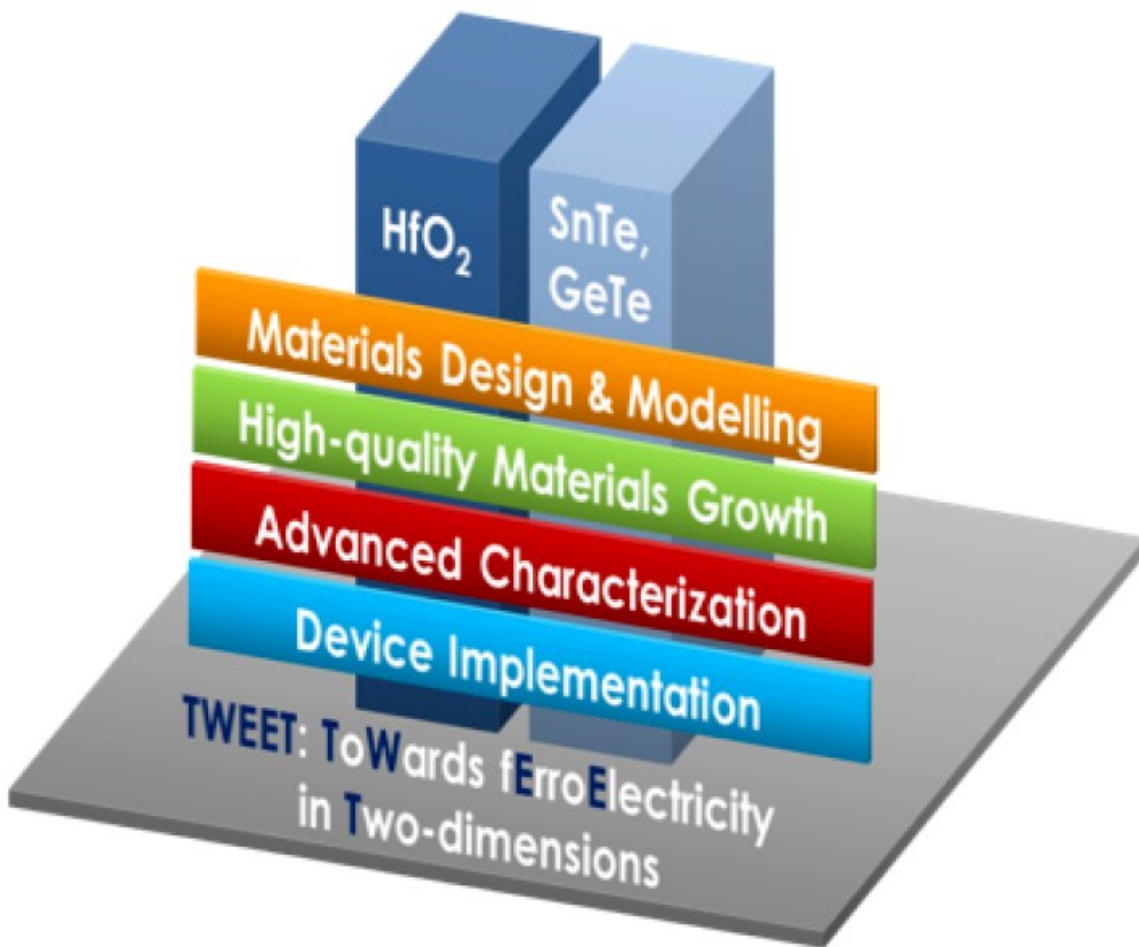
*Department of Physics, University of  
Naples, Federico II.*



# Contents

- Overview of the project
- Hafnium Zirconium Oxide (HZO)
- Germanium Telluride (GeTe)
- SHG measurements
- Magnetic measurements on HZO thin films
- Phase transition in pure and doped GeTe
- Conclusion

# TWEET overview

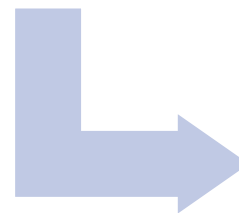


Material Design and modelling



- CNR-SPIN Chieti

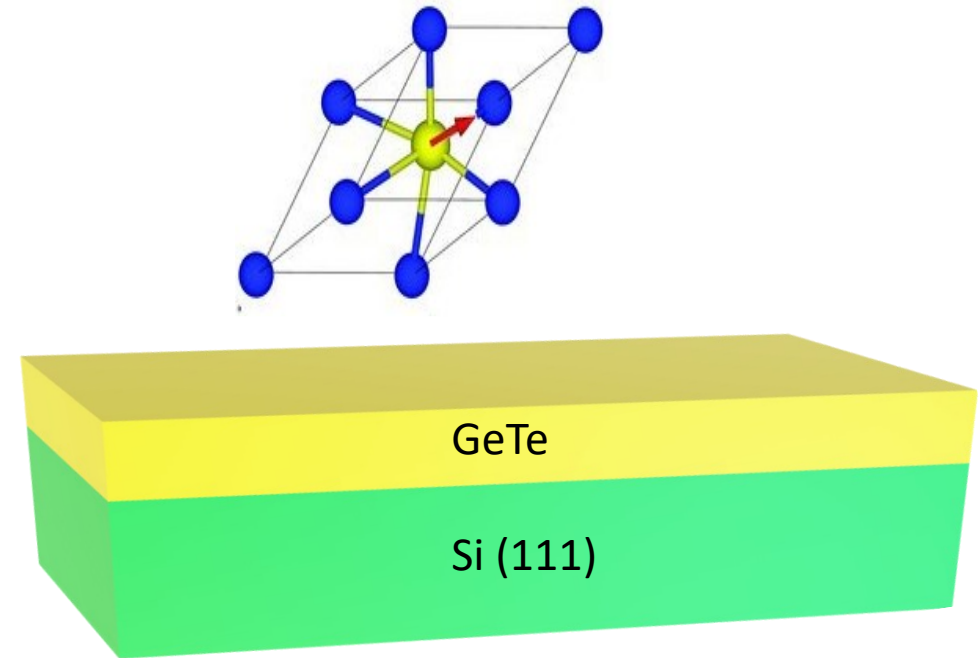
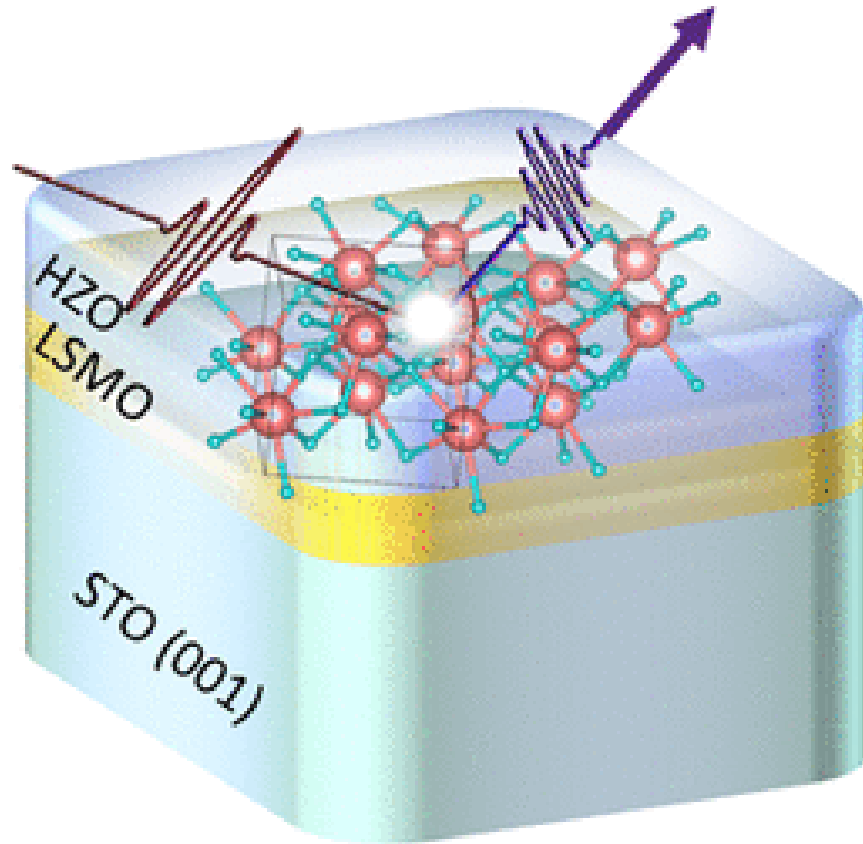
Fabrication and standard characterization



## Materials:

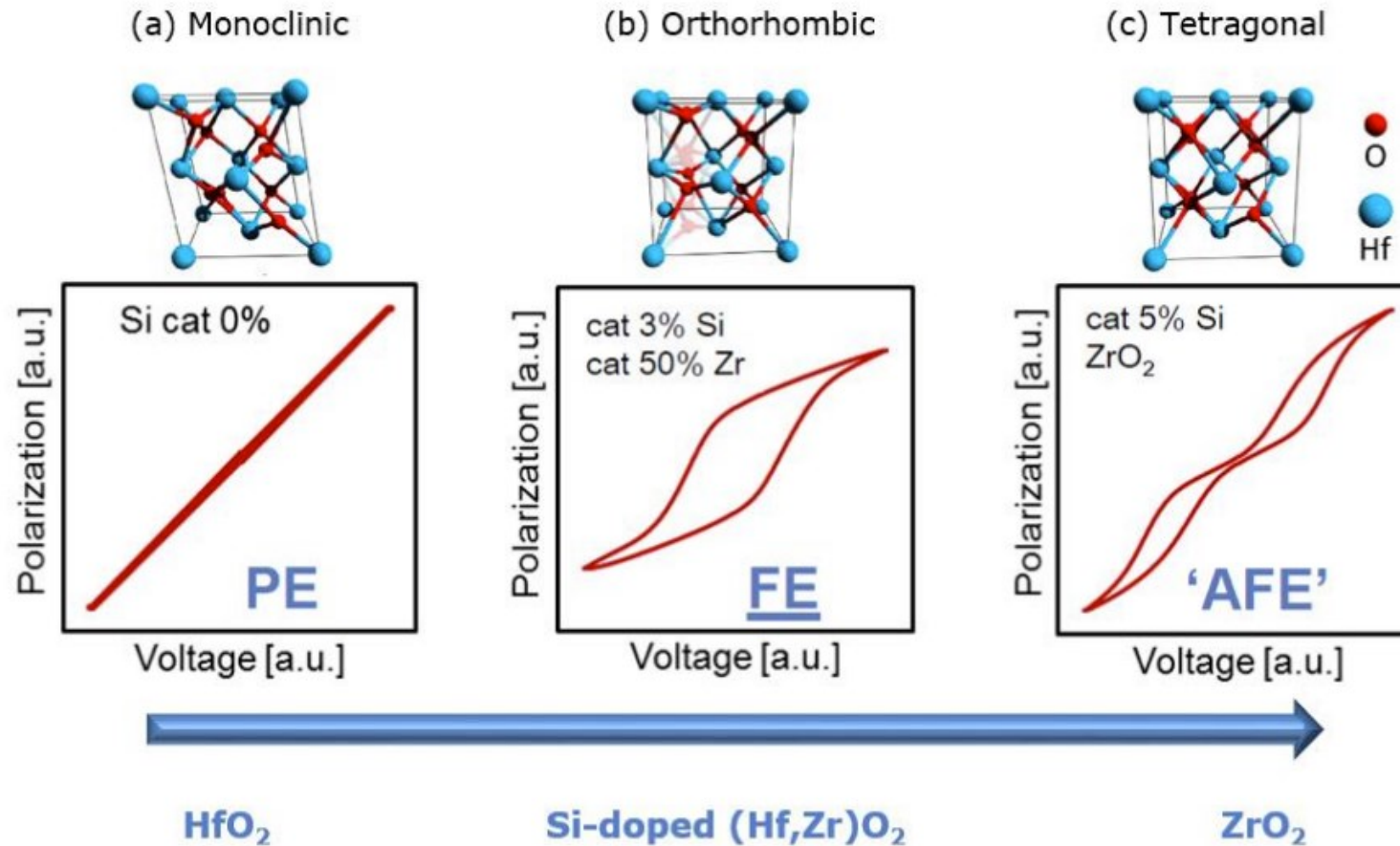
Hafnium Zirconium Oxide (HZO)

Germanium Telluride (GeTe)



# Hafnium Zirconium Oxide

## Crystalline phases of P-E cycle for different compositions of the system

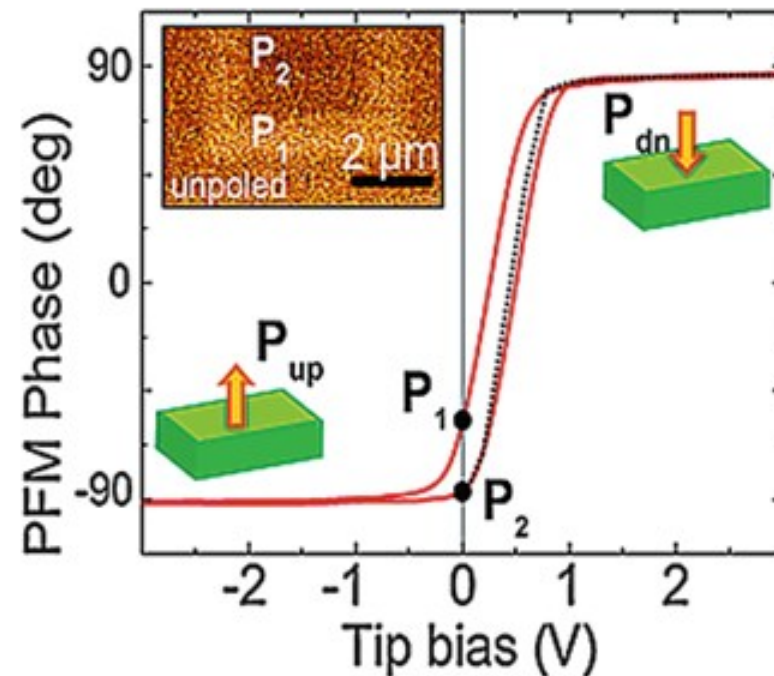
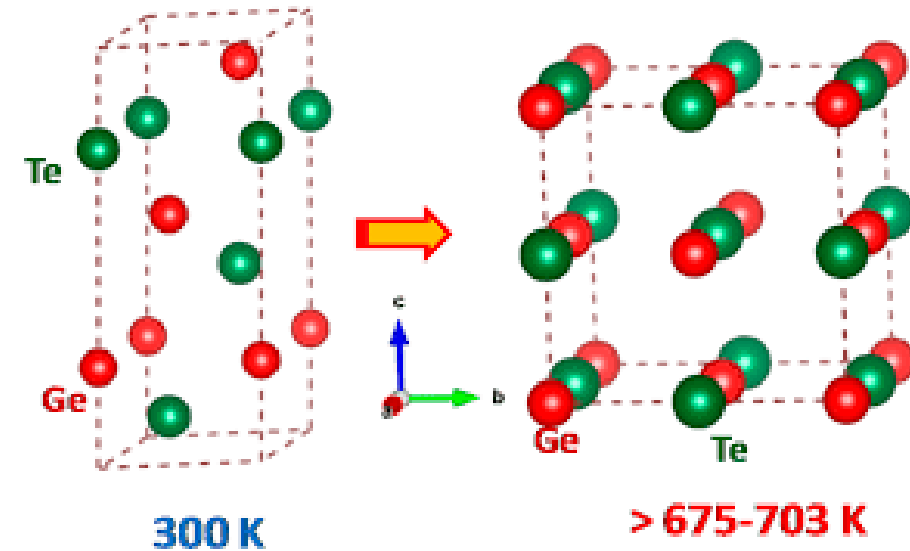


Claudia Richter, et .al. Si Doped Hafnium Oxide—A “Fragile” Ferroelectric System. Adv. Electron.Mater.2017, 3, 1700131.

# Germanium Telluride (GeTe)

## Germanium Telluride

- GeTe is Ferroelectric Rashba Semiconductor
- GeTe is Silicon compatible
- Rhombohedral unit cell of GeTe (polarization pointing along the pseudo-cubic [111] axis)
- FE hysteresis loop of GeTe(111) measured by piezo-force microscopy



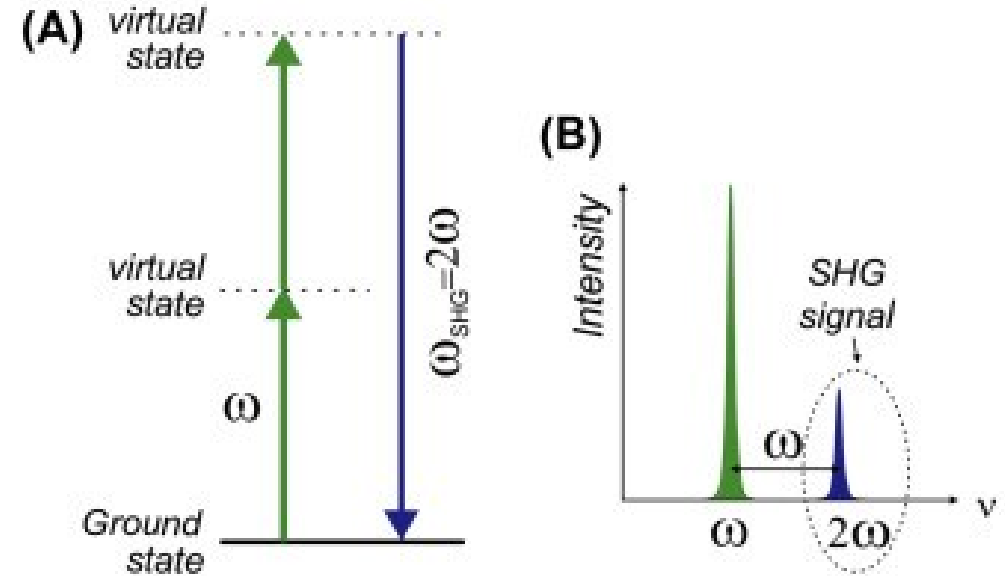
# Second Harmonic Generation (SHG)

## Laser matter interaction

$$P = \epsilon_0(\chi^{(1)}E_\omega + \chi^{(2)}E_\omega^2 + \chi^{(3)}E_\omega^3 + \dots)$$
$$= P^{(1)} + P^{NL}$$

$\chi^{(1)}$  describes the linear optics, e.g., how lens work.

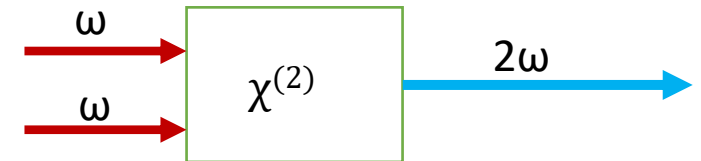
$\chi^{(2)}$  describes the second order effects such as SHG.



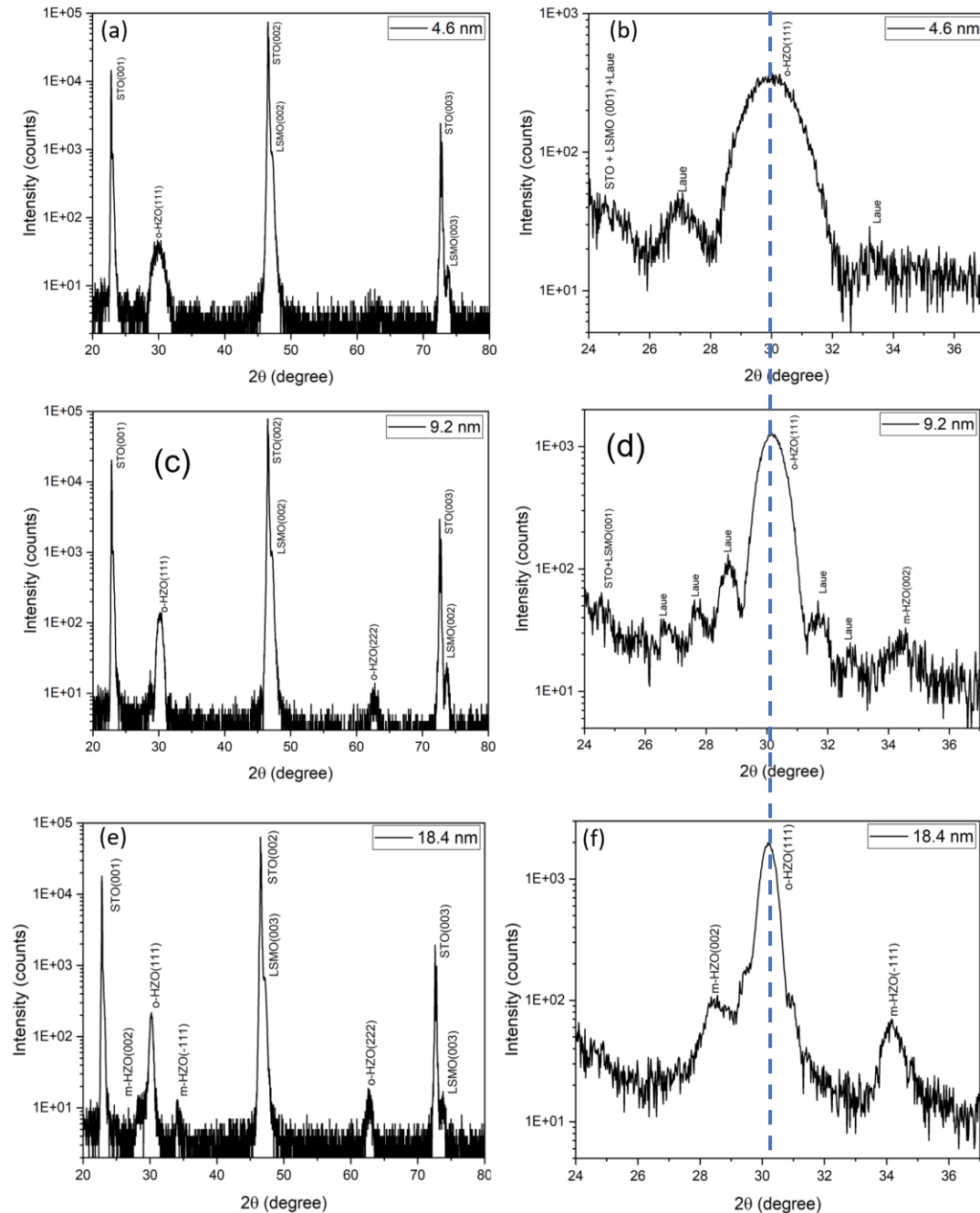
**Electric dipole SHG**  $P_i(2\omega) = \chi_{ijk}^{(2)} E_j(\omega)E_k(\omega)$

**Electric Quadrupole SHG**  $Q_i(2\omega) = \chi_{ijkl}^{(2)} E_j(\omega)K_kE_l(\omega)$

## Ferroelectrics



# XRD Results of HZO

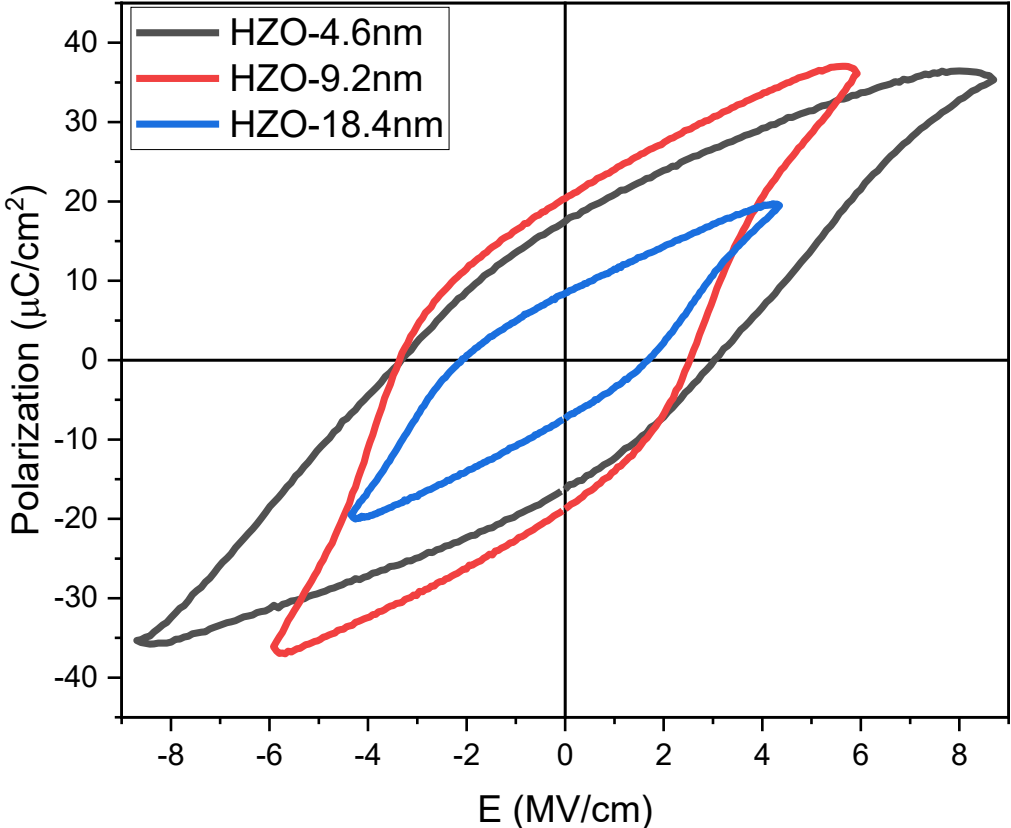


- Peak shifts at smaller angles indicating  $d_{111}$  elongation in thinner films (orthorhombic phase)
- 9.2 nm HZO thin film has largest remanent polarization

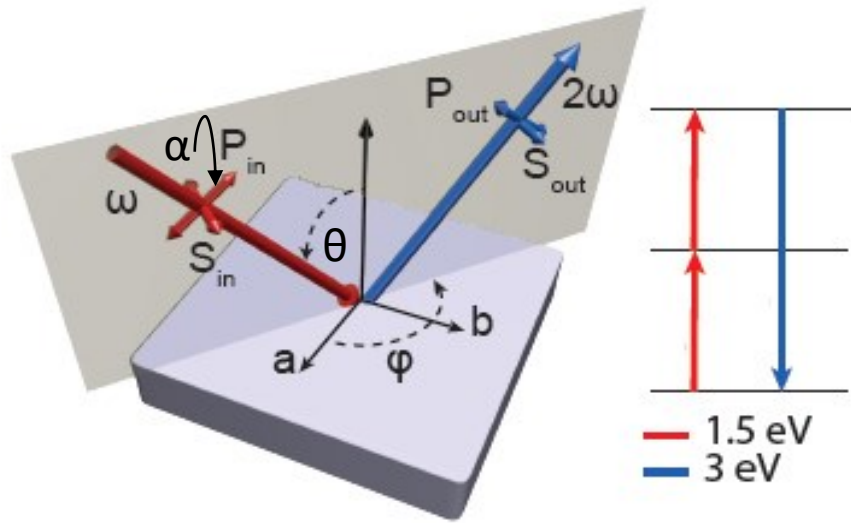
Done at ICMAB



# Electrical measurements

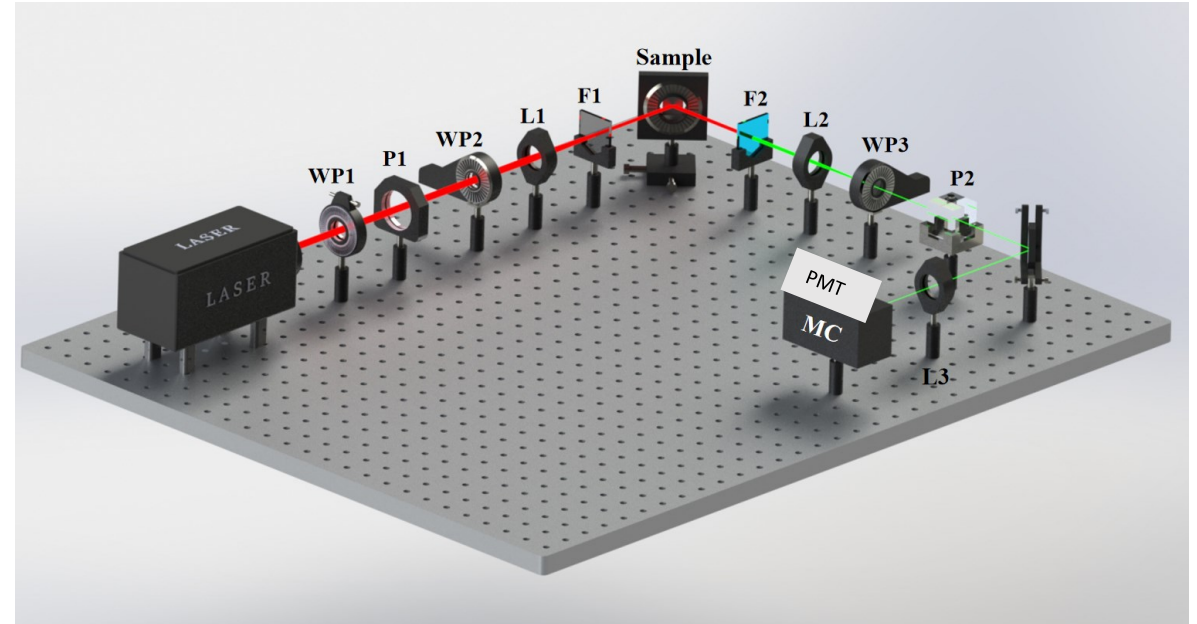


# Experimental Geometry

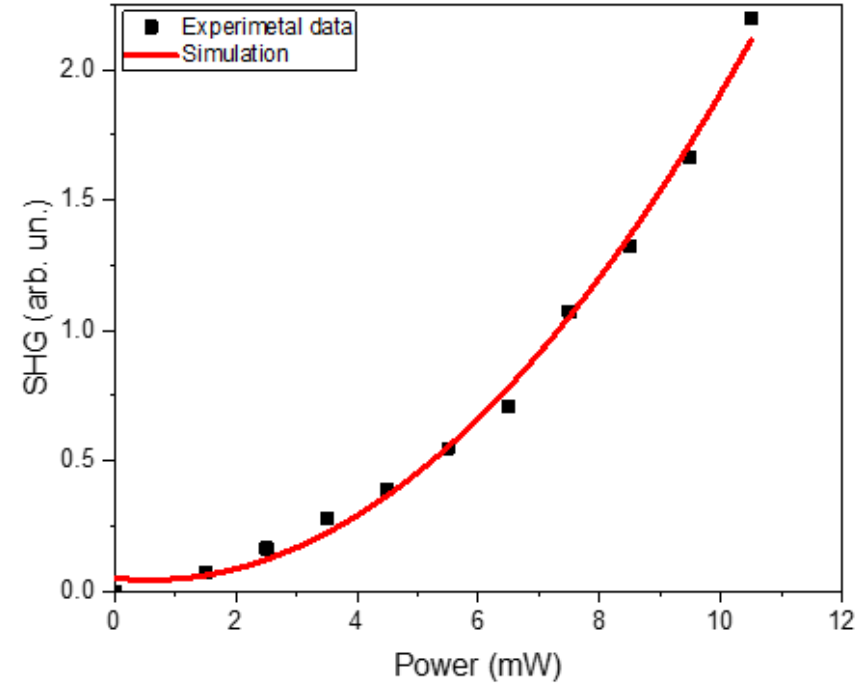
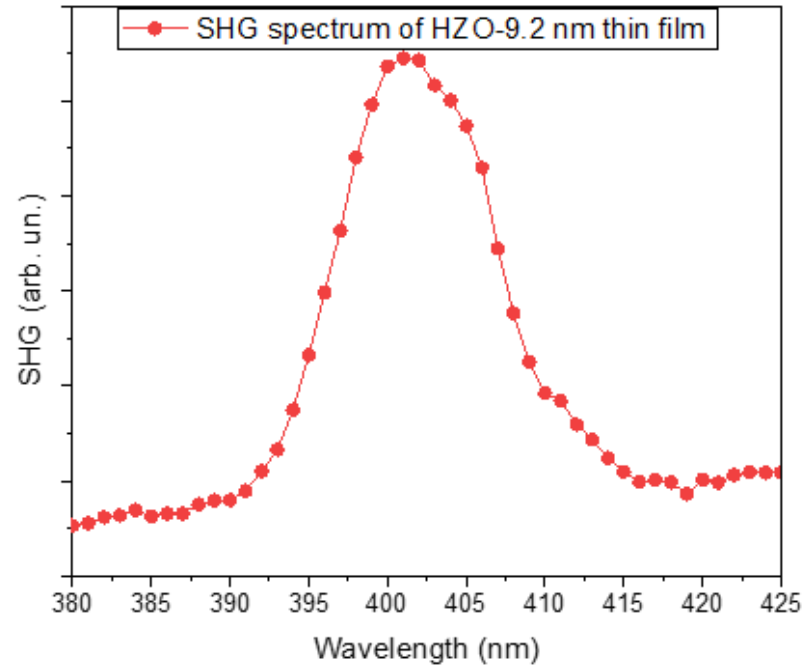


Alpha  $\alpha$  : Polarization angle  
 $\phi$  : Sample azimuthal angle  
 $\theta$  : Angle of incidence

# Experimental set up (Beam path)

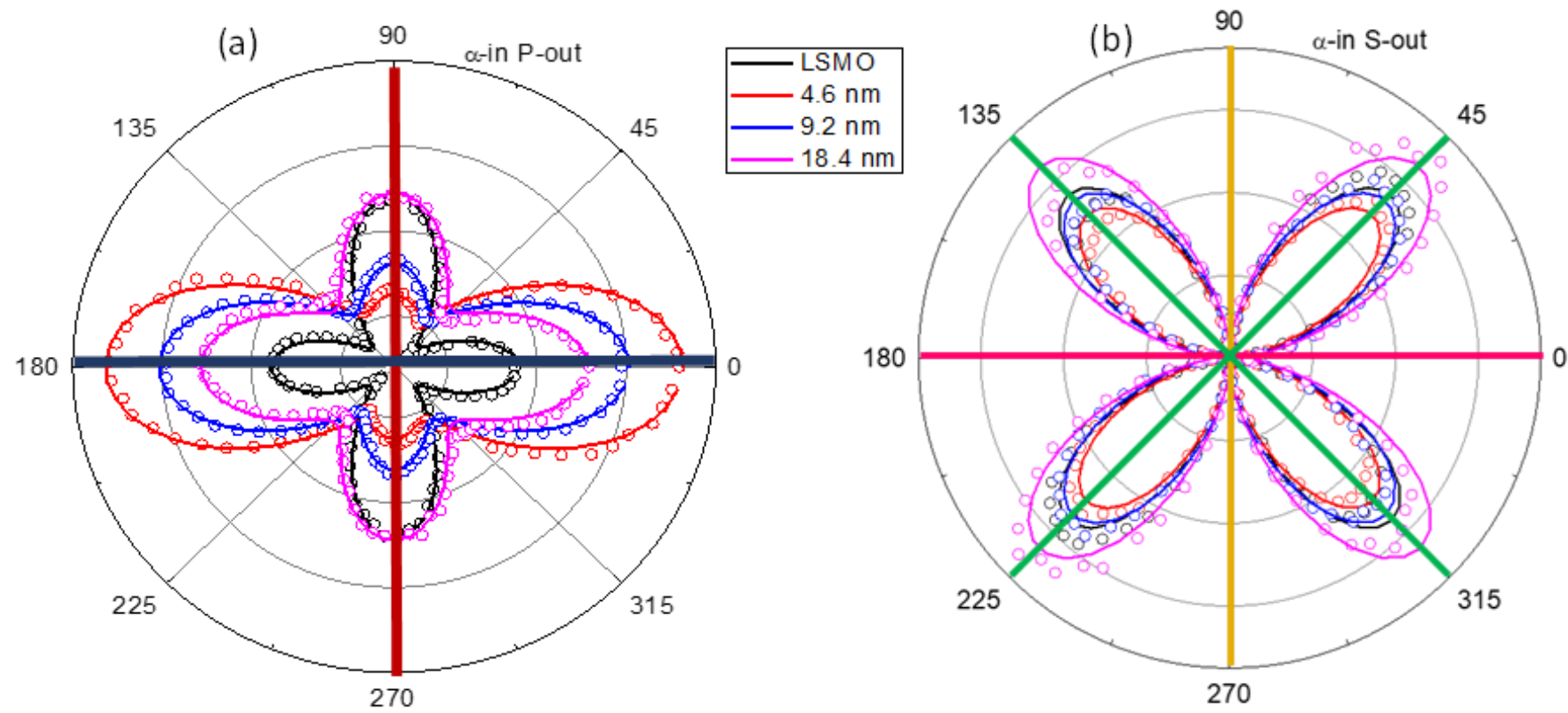


# Spectral and power characterization of SHG

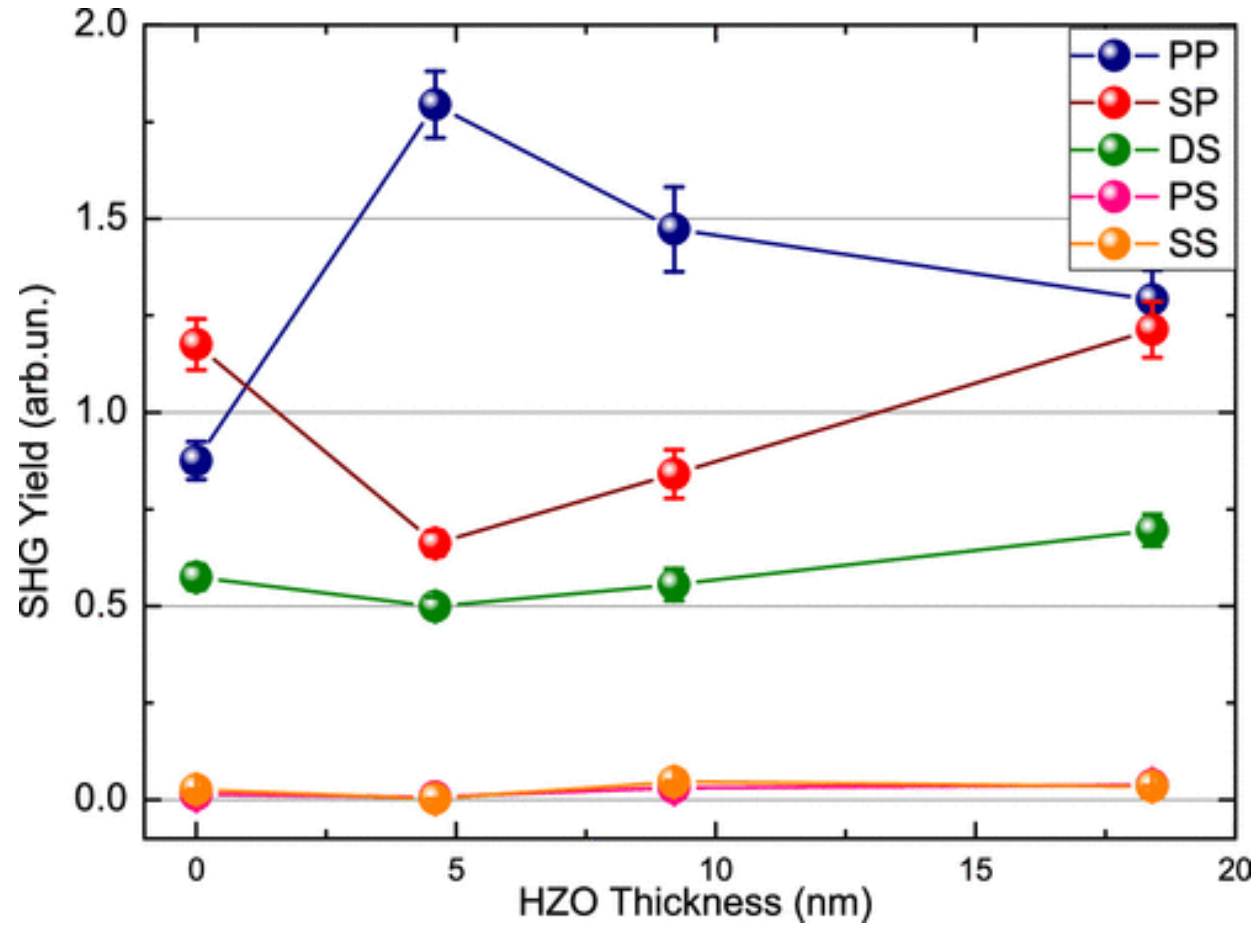


# SHG results

## Alpha scans

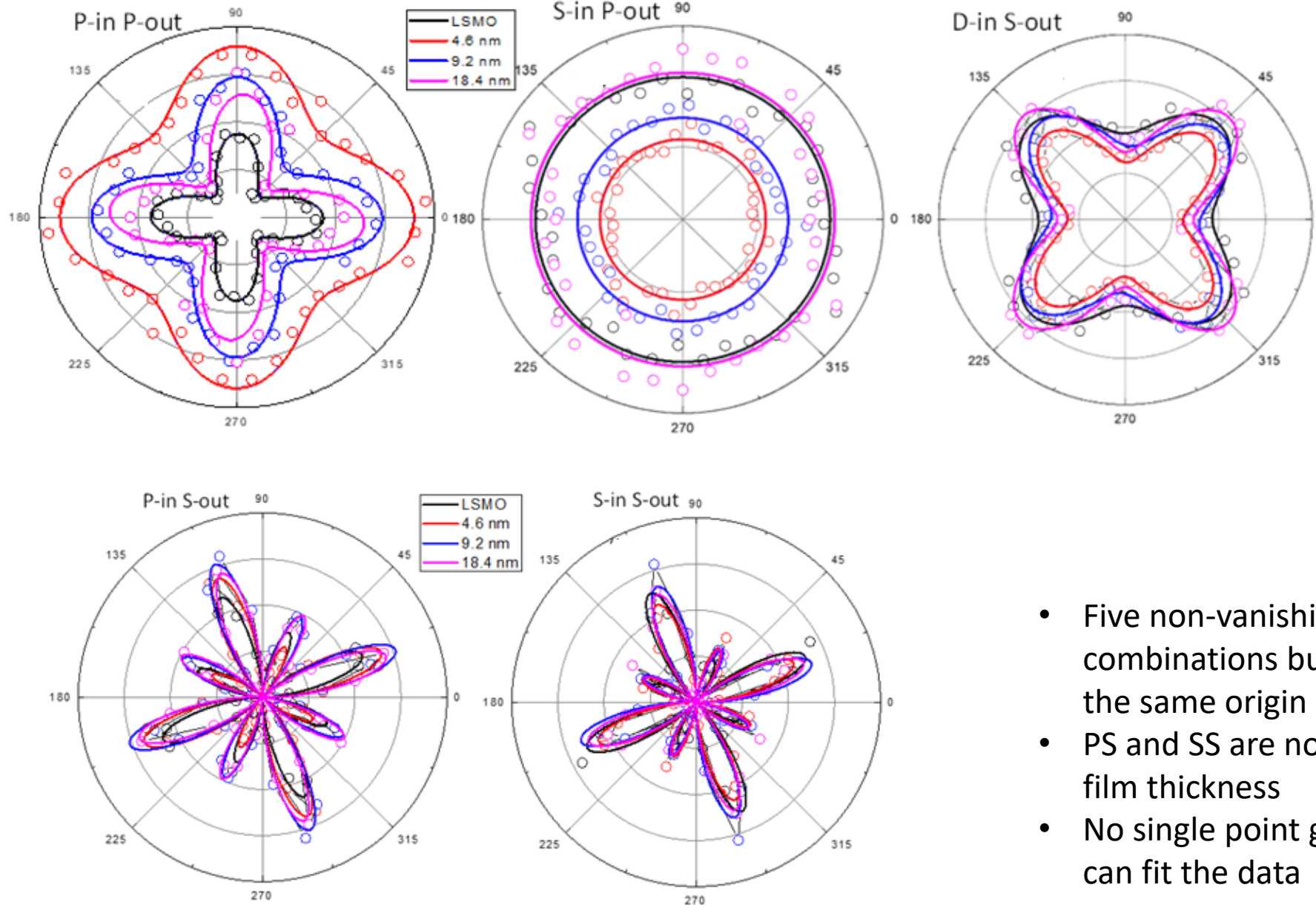


### SHG signal in different polarization combination



- HZO coverage affects the SHG components
- PP has a maximum for thinnest and SP has a minimum

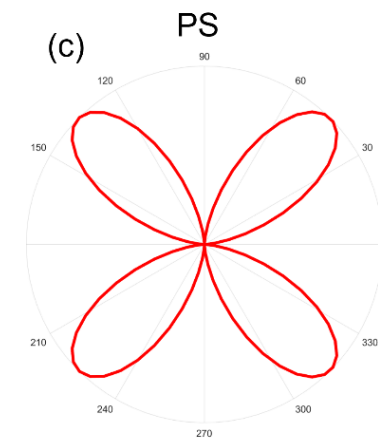
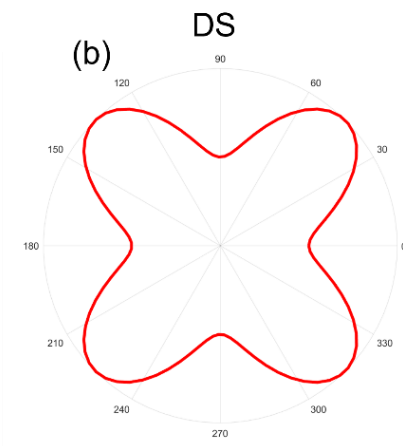
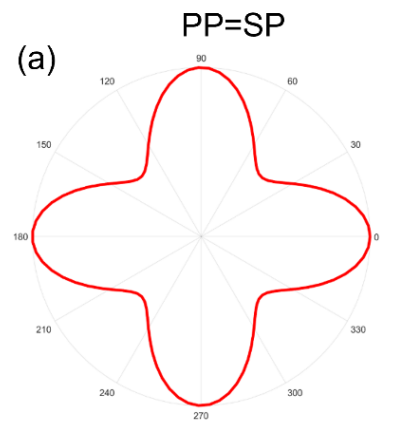
## Azimuthal Scans



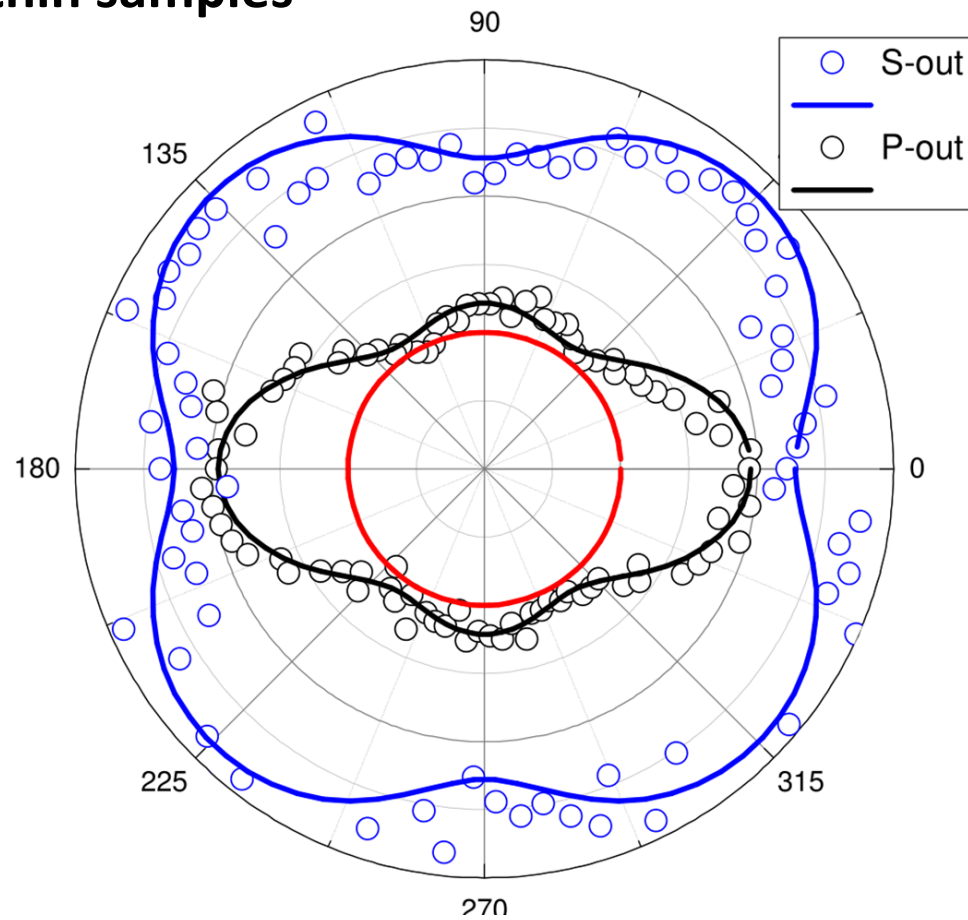
- Five non-vanishing polarization combinations but they don't belong to the same origin
- PS and SS are not changing with the film thickness
- No single point group symmetry that can fit the data

## Looking for a real symmetry ?

| Symmetry     | Non-vanishing elements                                |
|--------------|---|
| o-HZO, mm2   | $zxz = xxz$<br>$yyz = yzy$<br>$zxx$<br>$zyy$<br>$zzz$ |
| m-HZO, 2/m   | Each element vanishes.                                |
| t-HZO, 4/mmm | Each element vanishes.                                |



## Ratio b/w LSMO-thick and LSMO-thin samples



Blue curve represents the S-out ratio between LSMO thick and LSMO thin samples.

*Set 2: LSMO = 8 and 20 nm  
HZO = 9 nm*

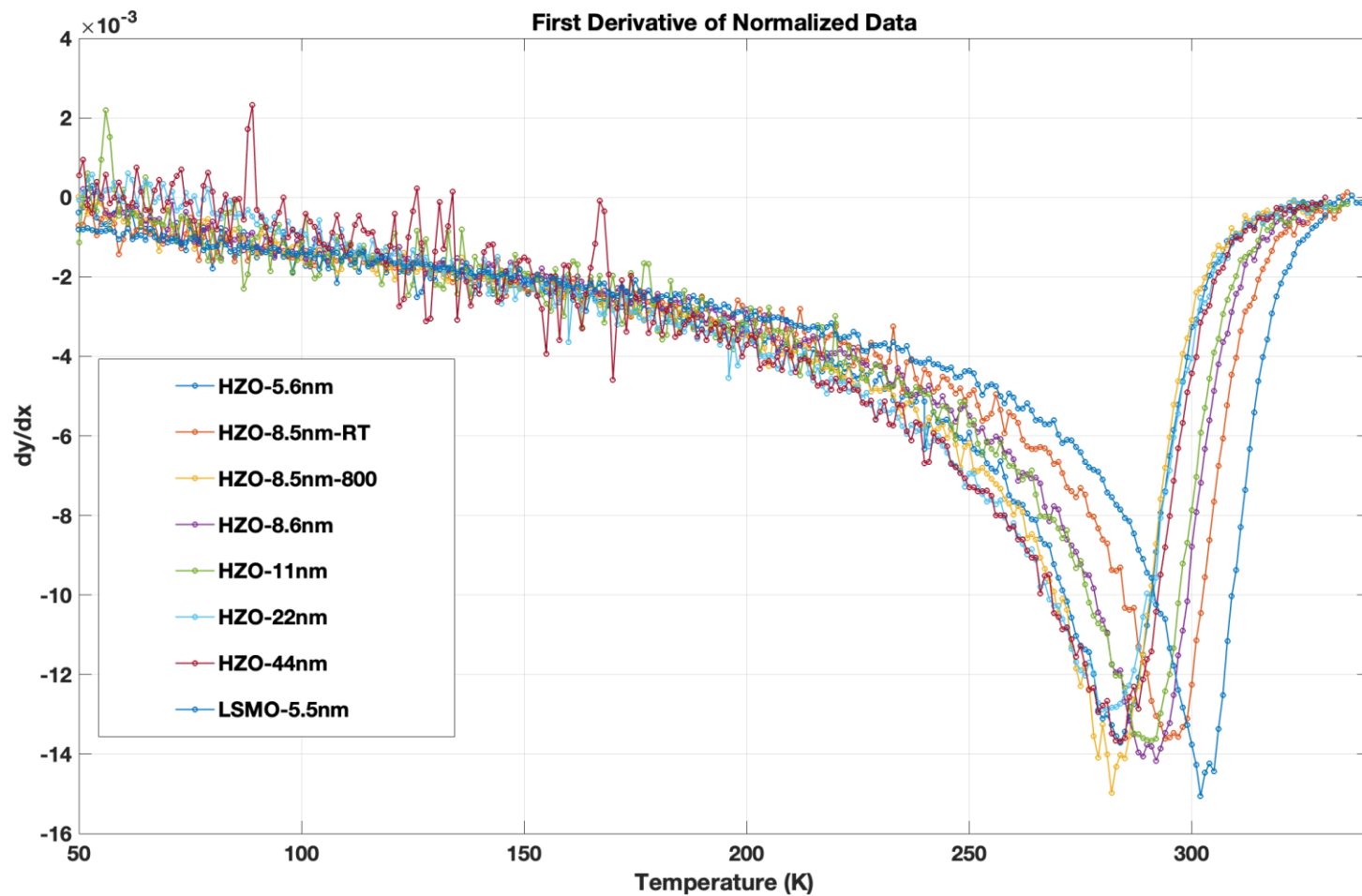
- If the SHG signal was scaling with LMSO then we should have a circle.
- In case of S-out, it seems a circle but in P-out, there is an elongation in PP direction and SP component is lying almost around 1.
- This suggests that SHG cannot be solely LSMO bulk dependent but there is an interfacial contribution too.



# **Magnetic measurements on HZO thin films**



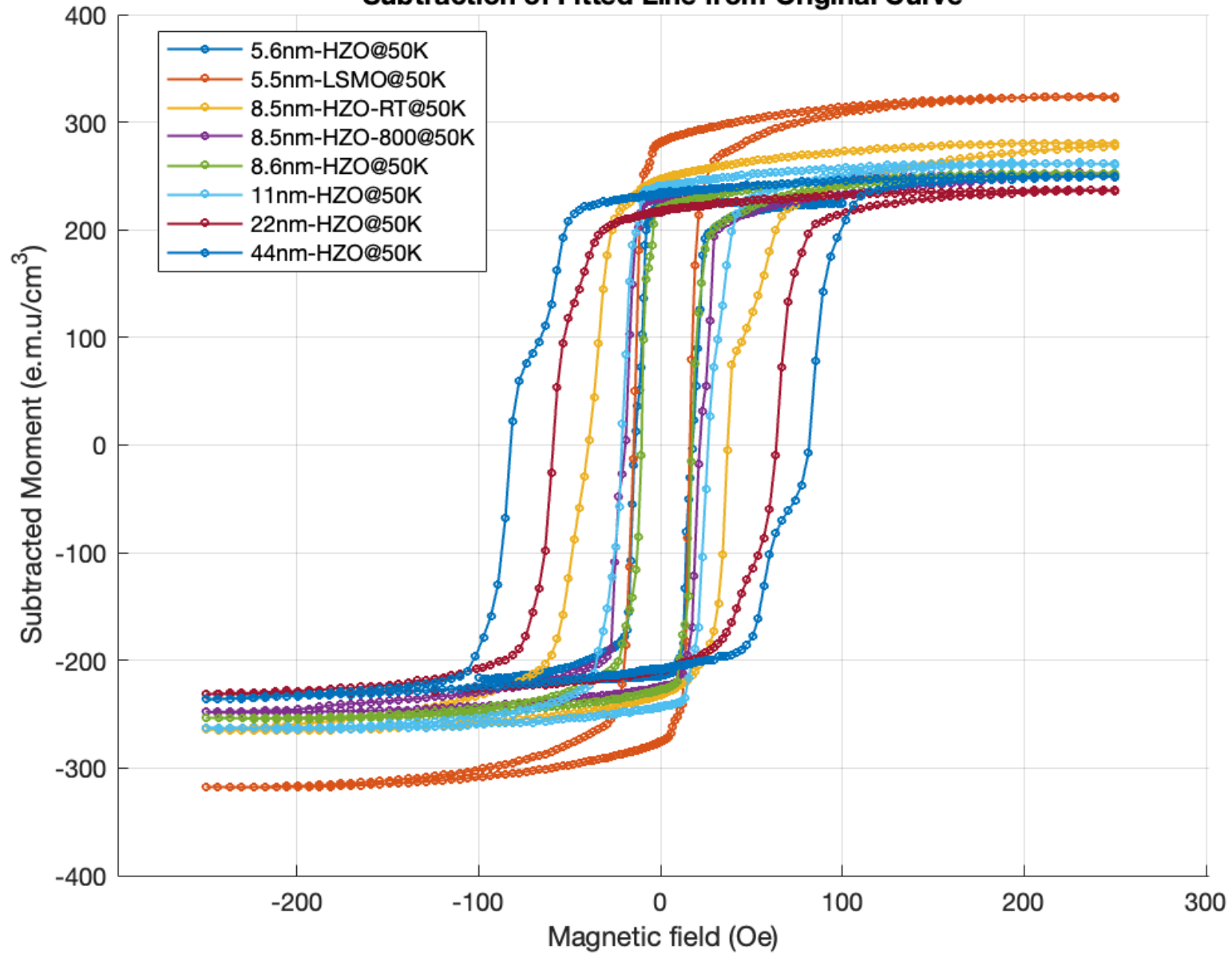
# To find Tc, we use first derivative



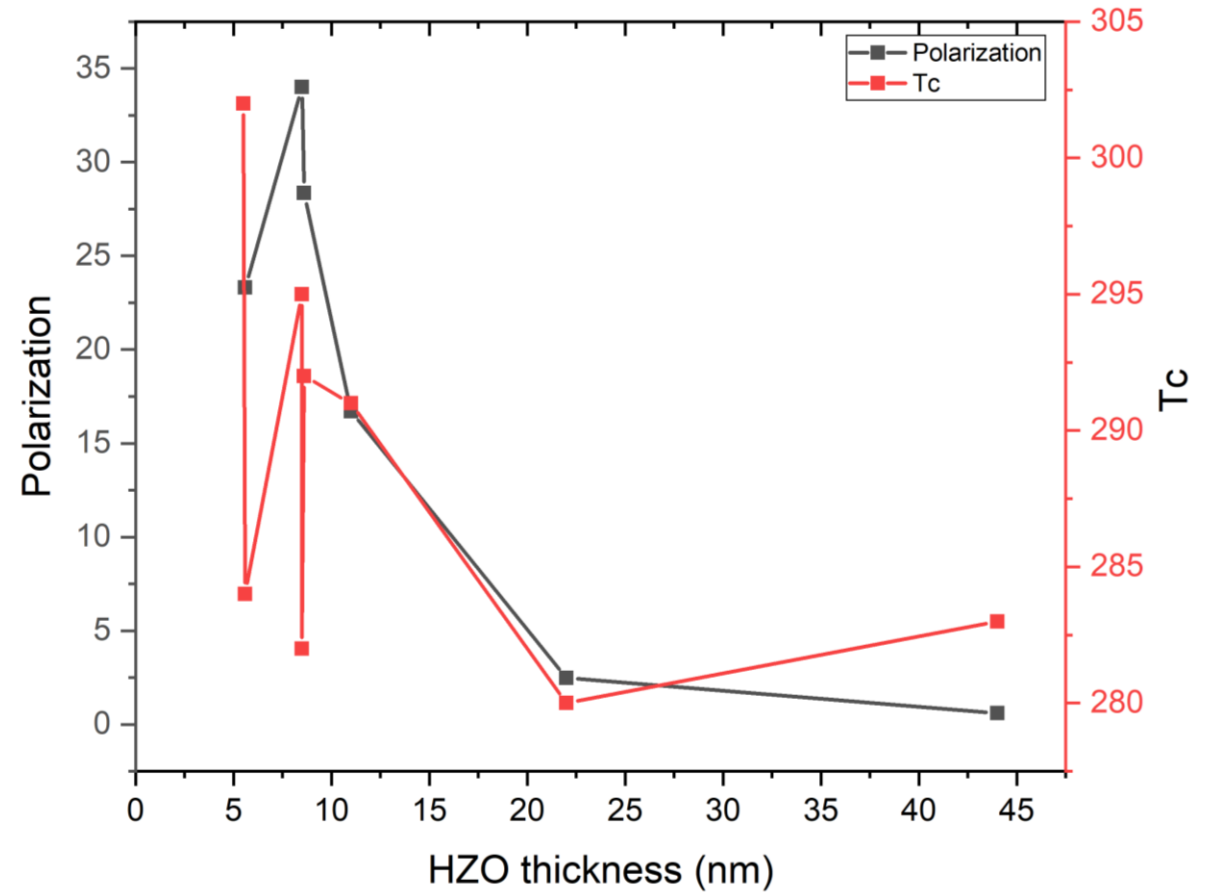
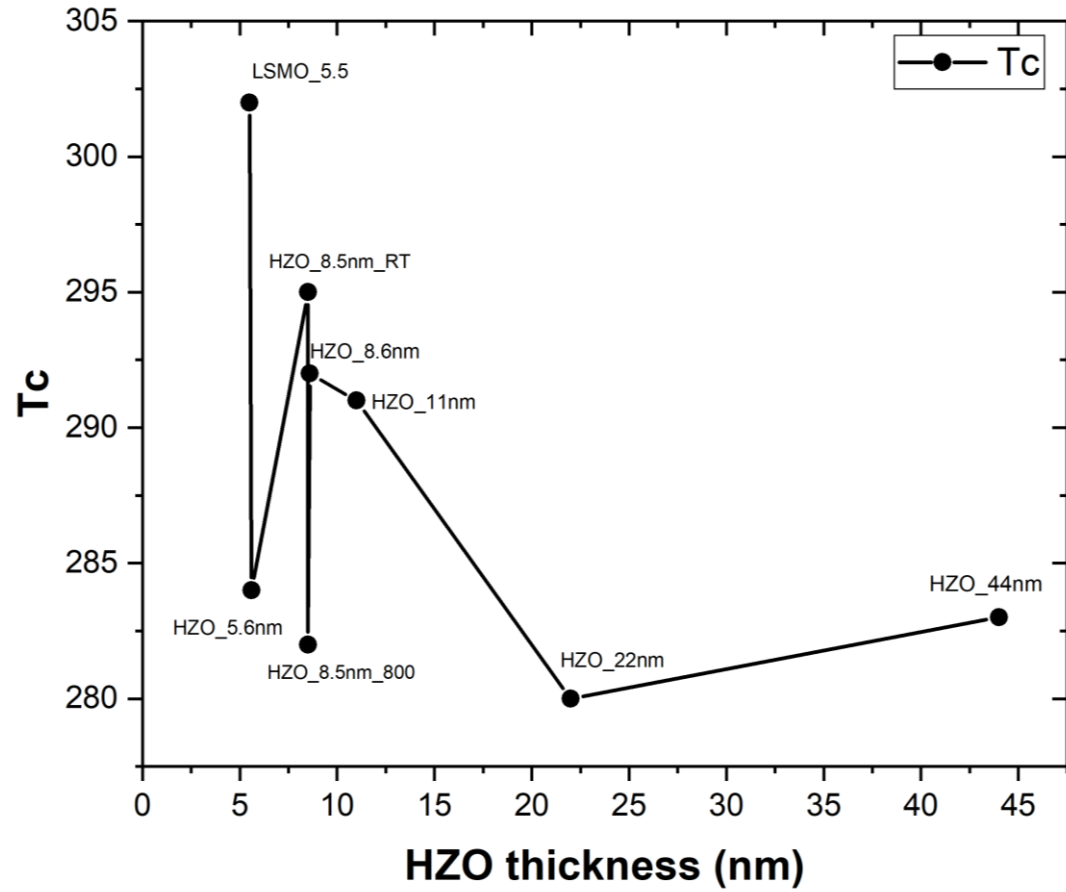
| Sample        | Tc (K) |
|---------------|--------|
| LSMO_5.5nm    | 302    |
| HZO_5.6nm     | 284    |
| HZO_8.5nm_RT  | 295    |
| HZO_8.5nm_800 | 282    |
| HZO_8.6nm     | 292    |
| HZO_11nm      | 291    |
| HZO_22nm      | 280    |
| HZO_44nm      | 283    |

# M vs H for HZO thin films

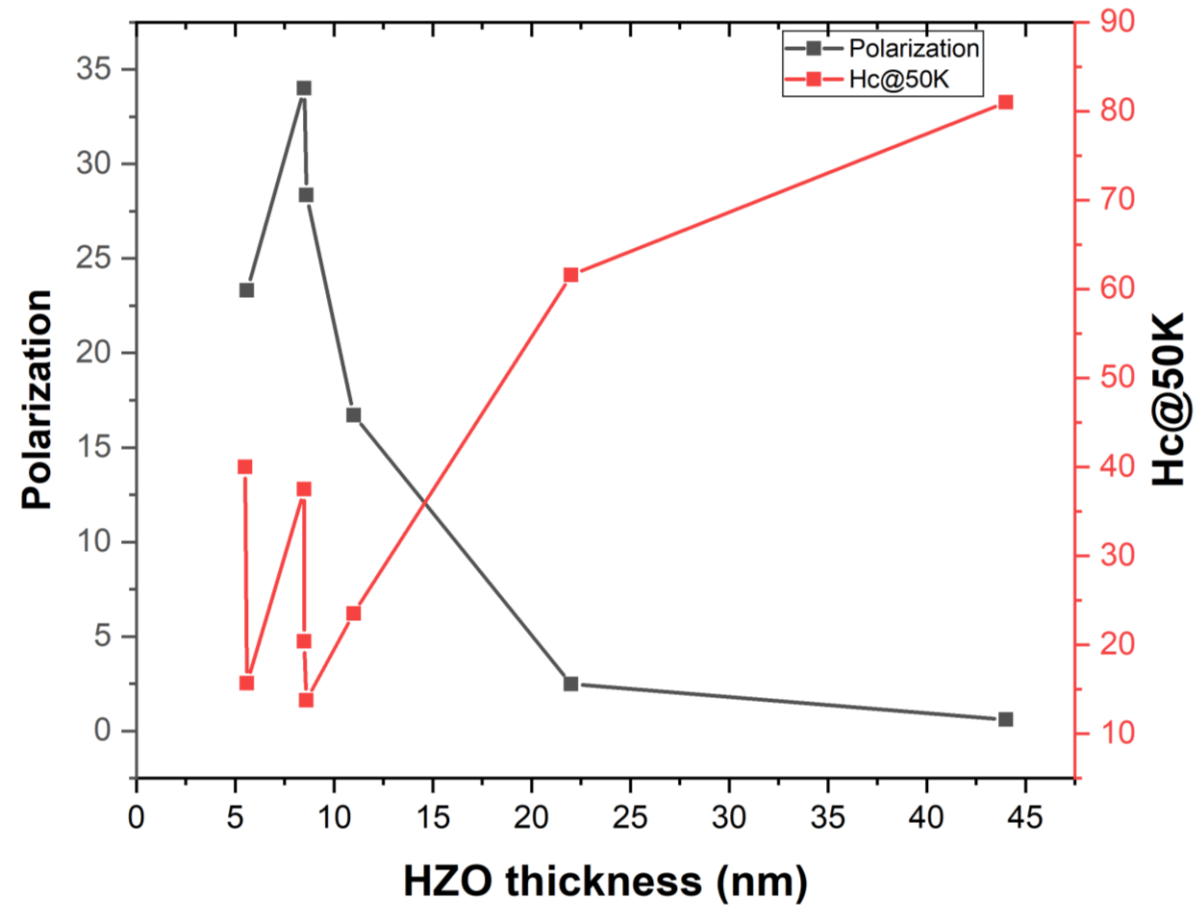
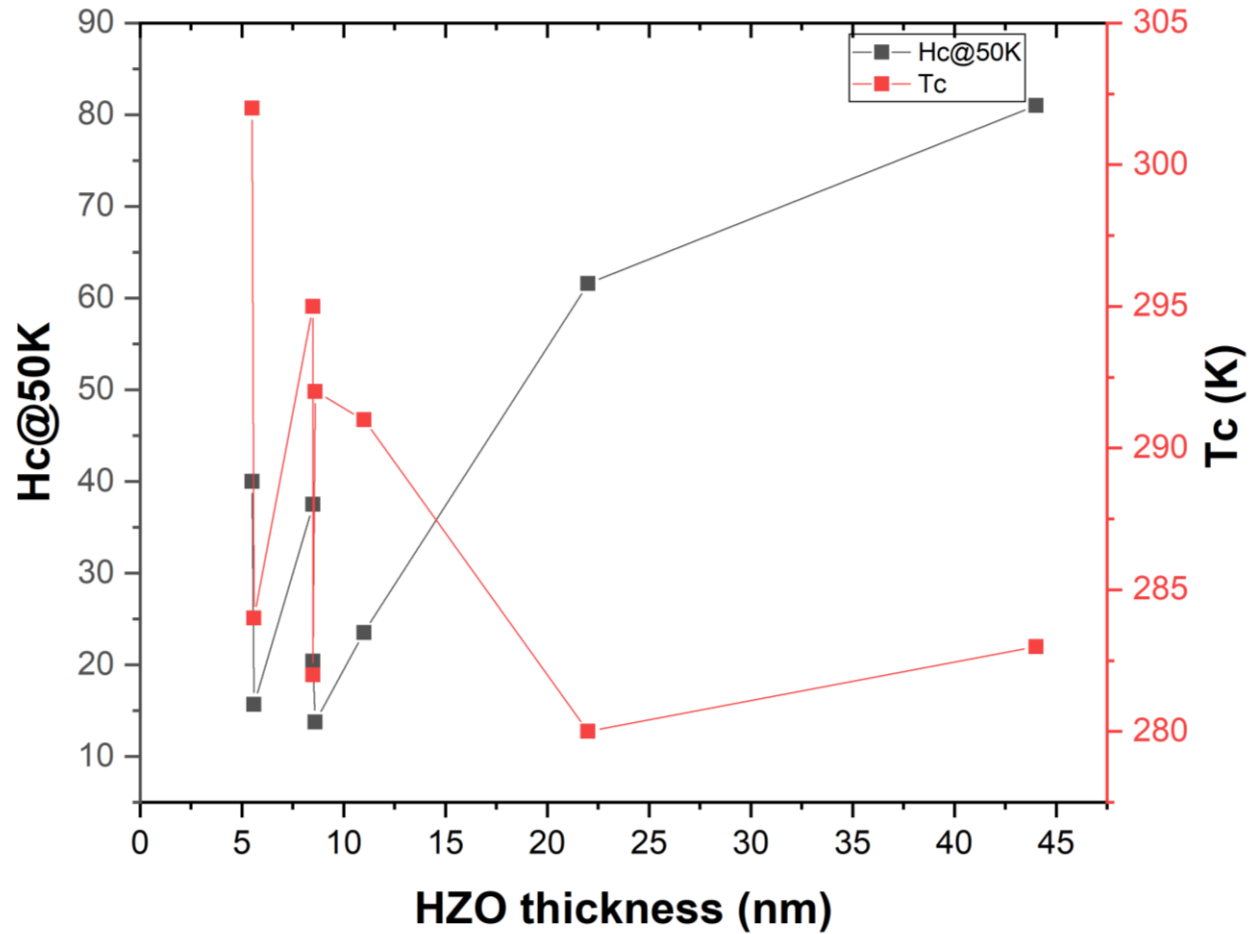
## Subtraction of Fitted Line from Original Curve



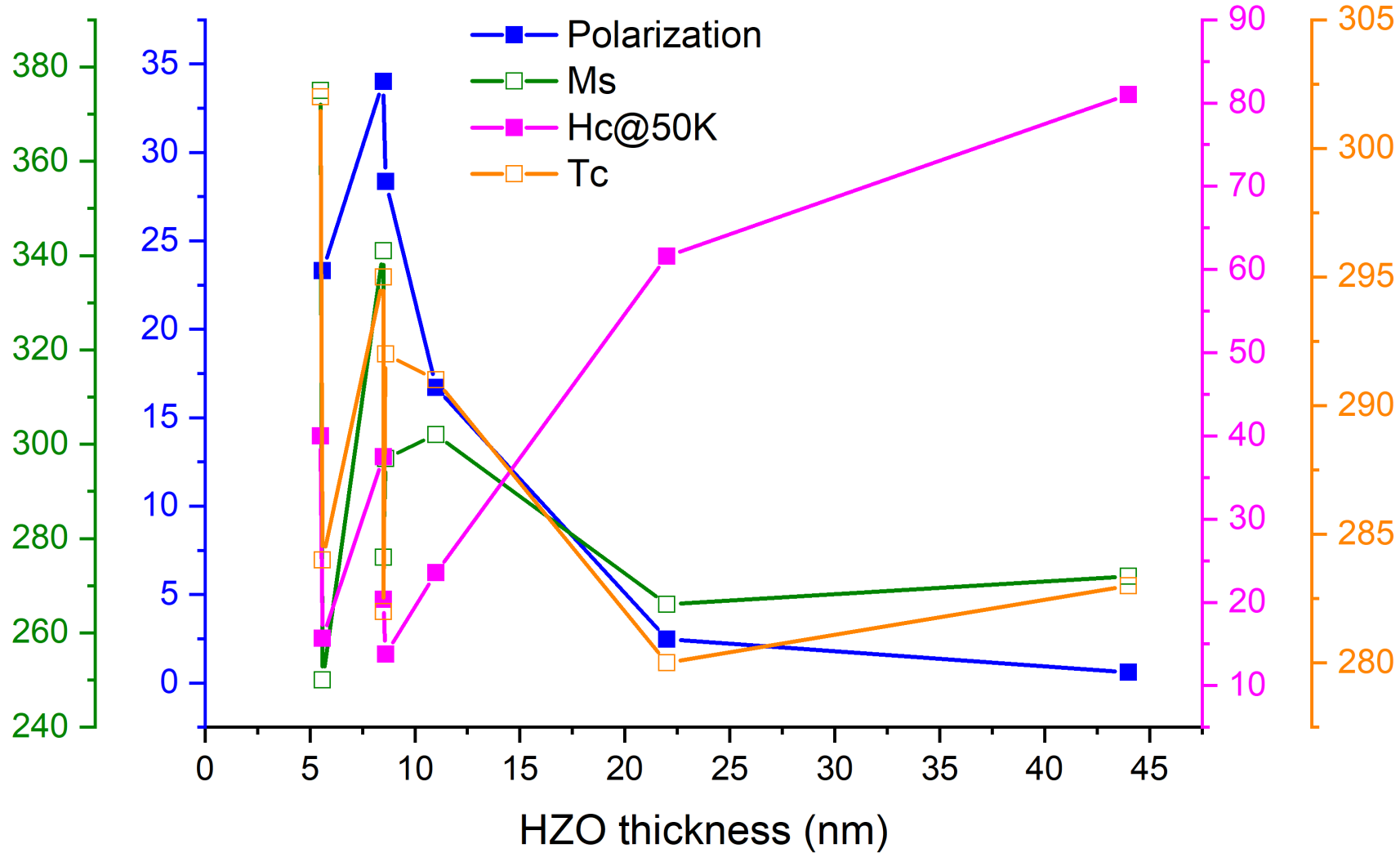
# HZO thickness vs Tc vs Polarization



# Magnetic coercivity vs Tc vs Polarization



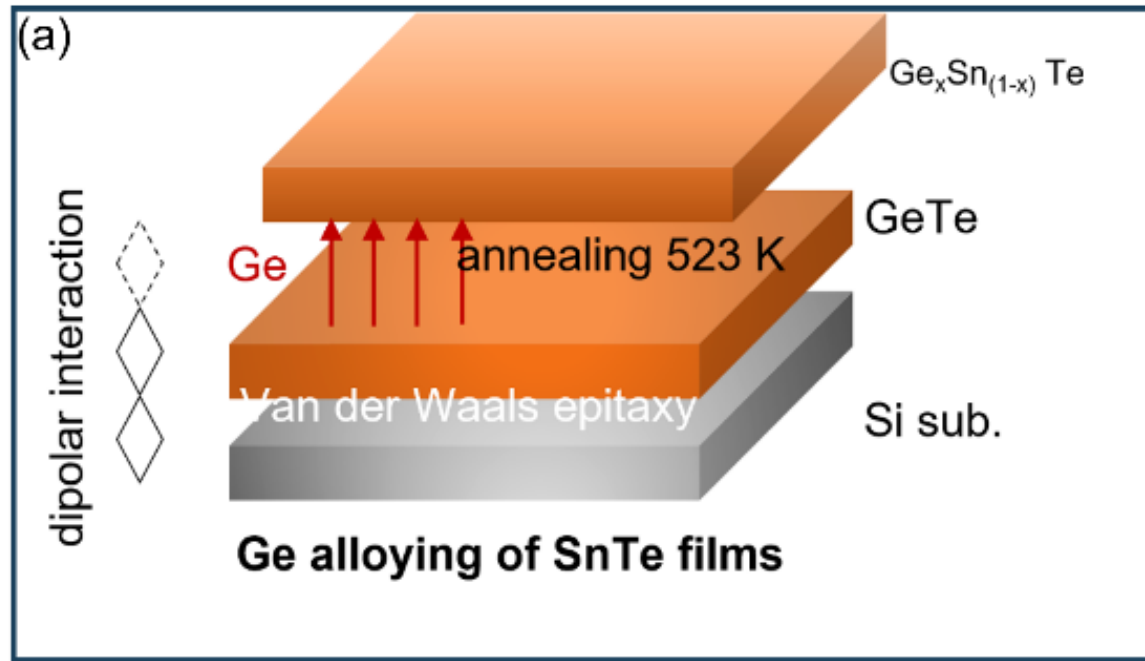
# All parameters together



## **Part II Germanium Telluride**

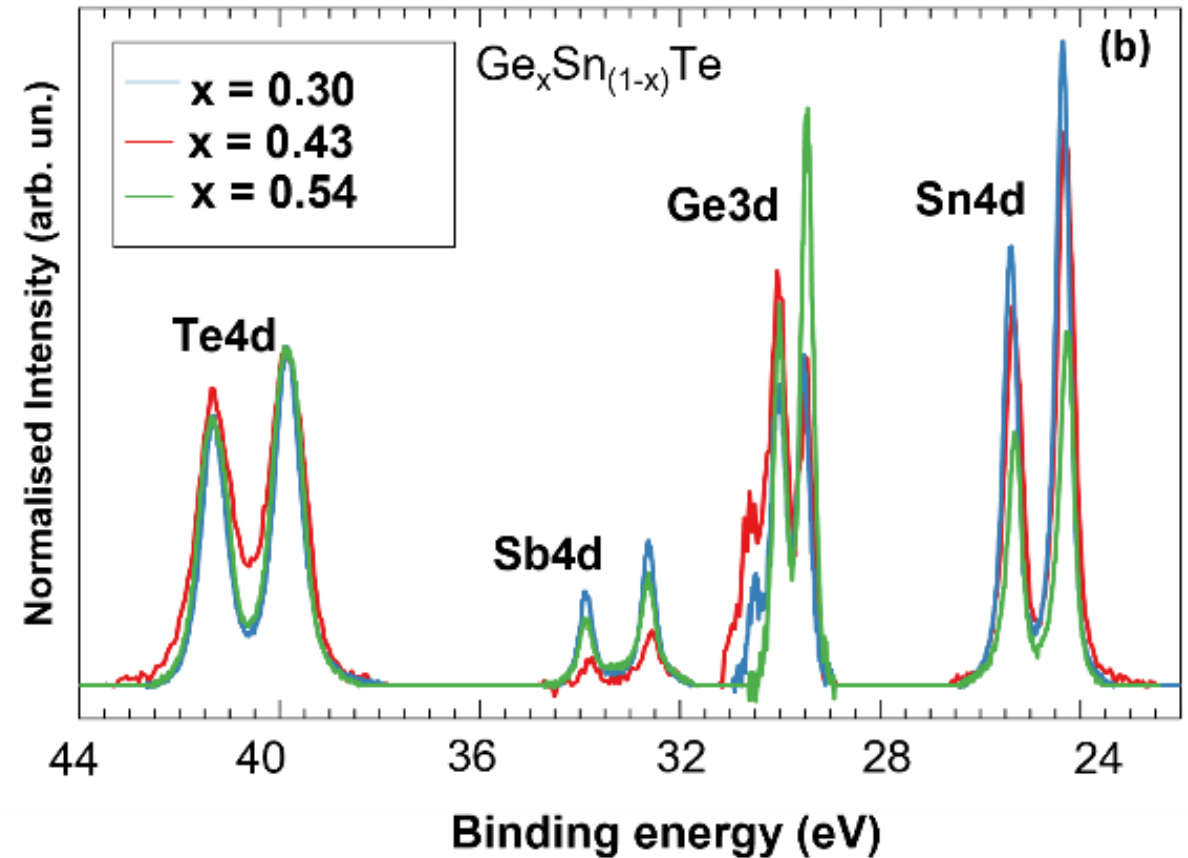


## Growth and Characterization of Pure and doped GeTe

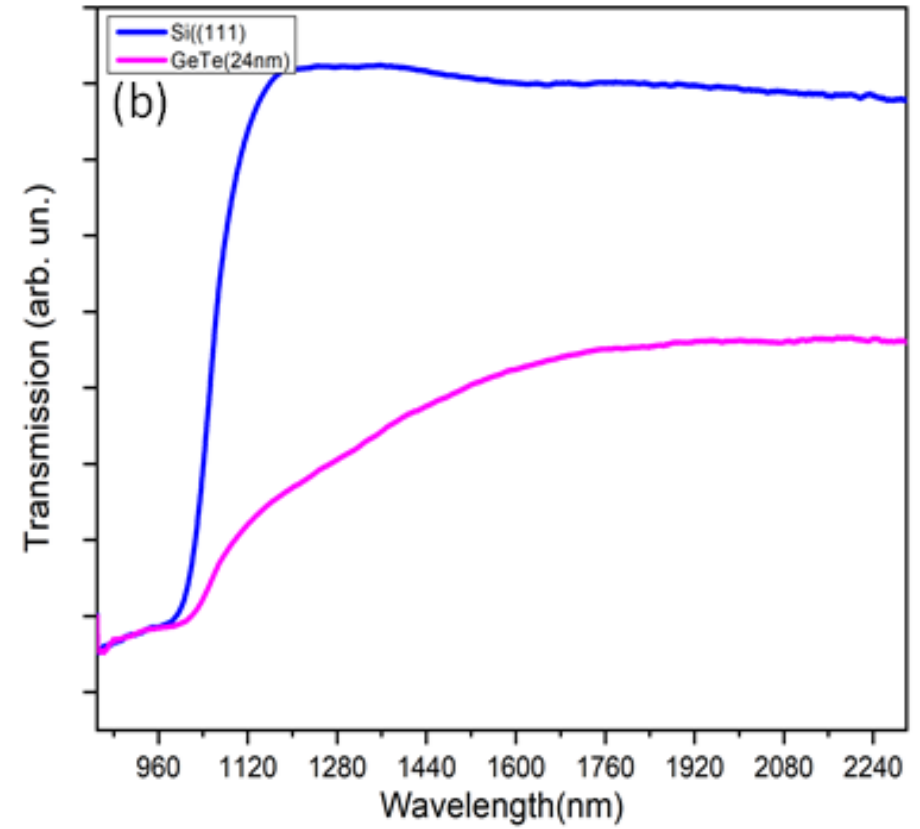
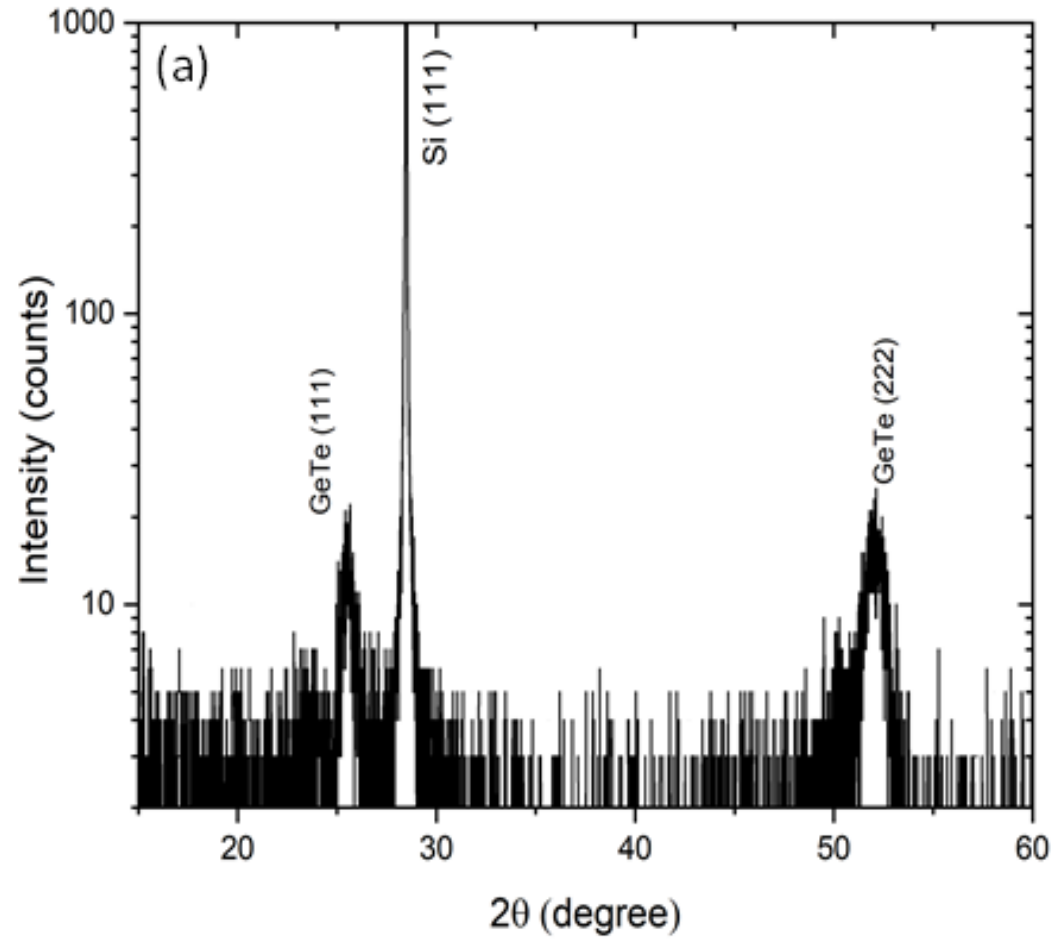


**MBE Process:** Diffusion of Ge into SnTe matrix when two layers of GeTe and SnTe were grown on top of each other

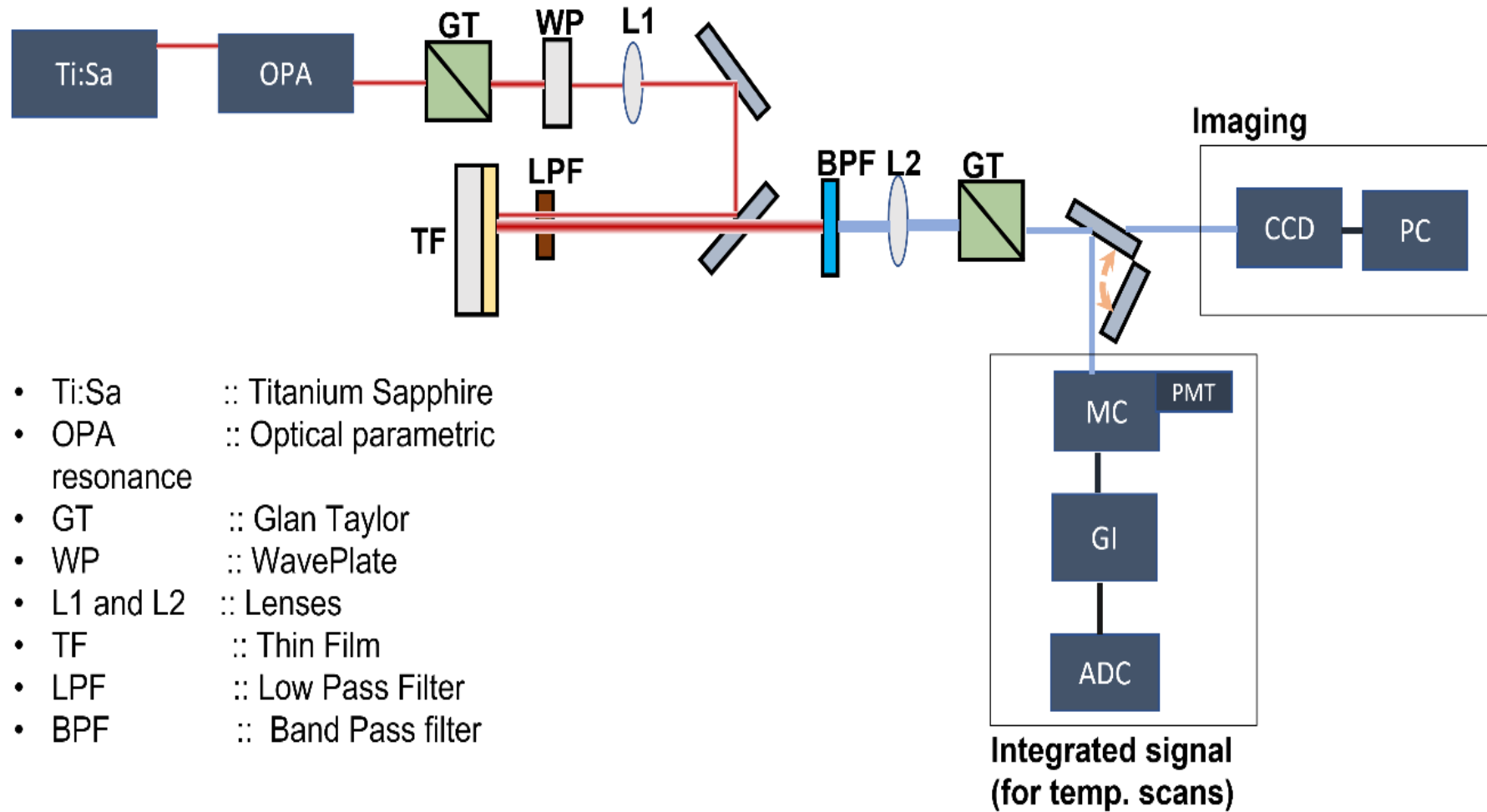
Done by collaboration with PoliMi



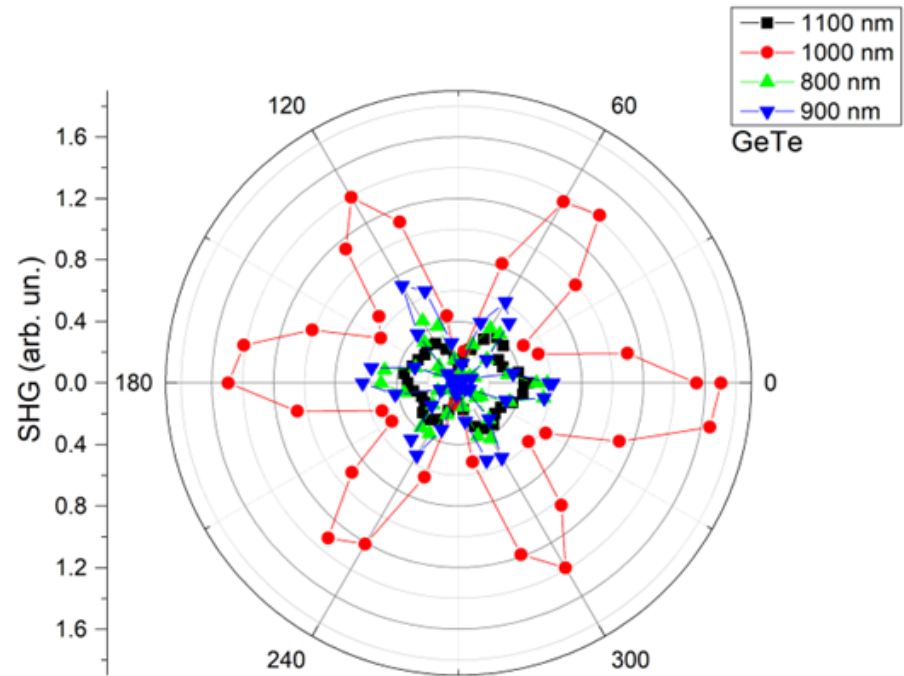
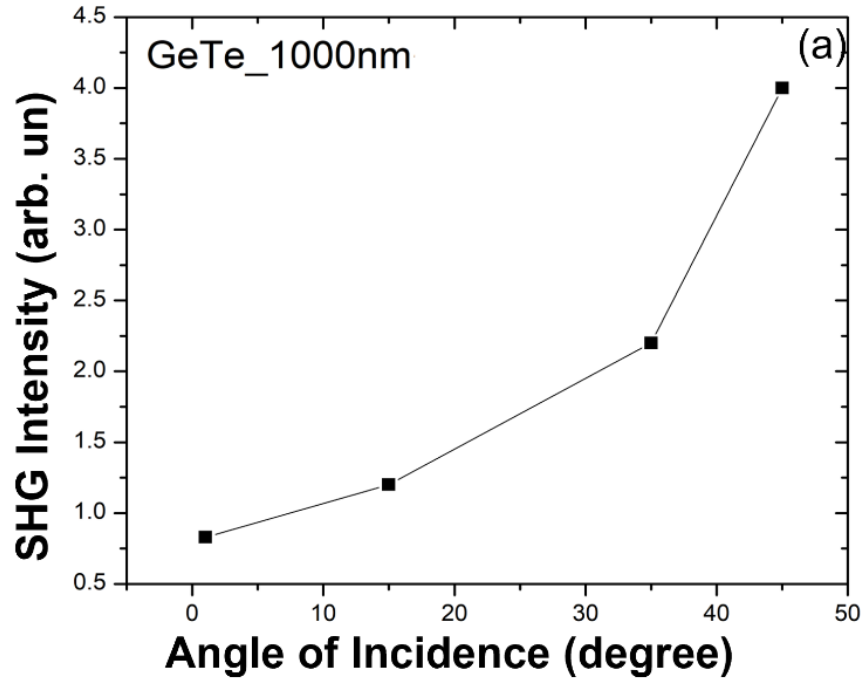
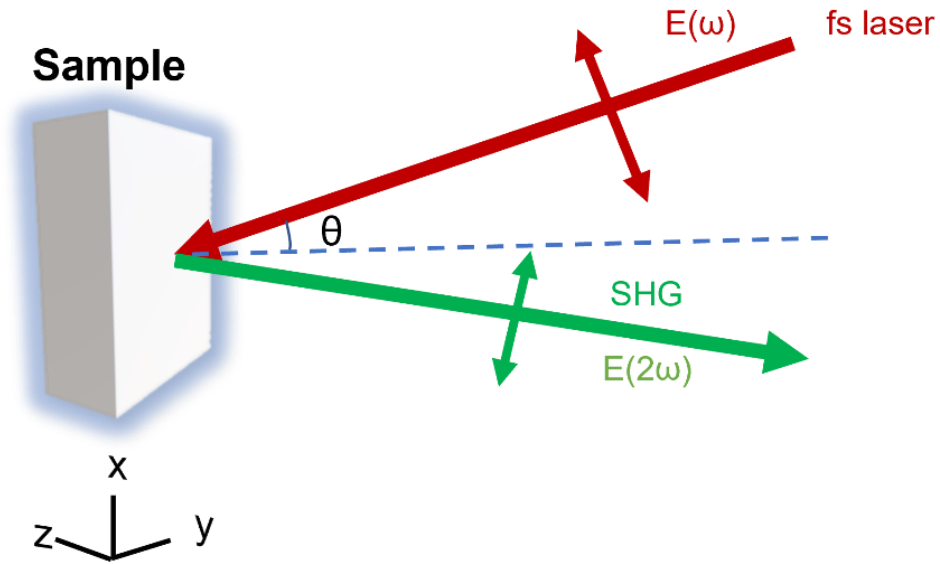
# XRD and Linear spectra



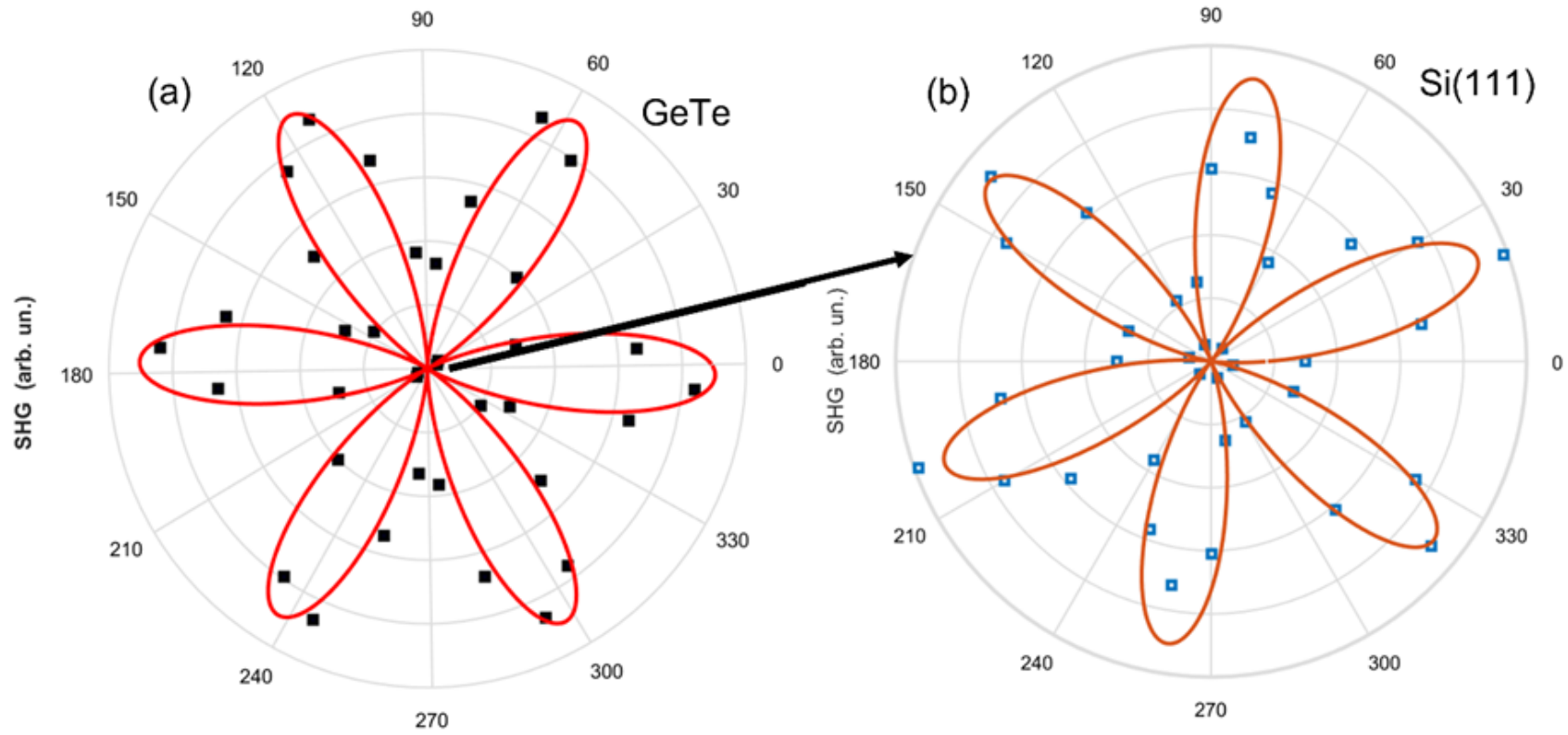
# Optical SHG set-up



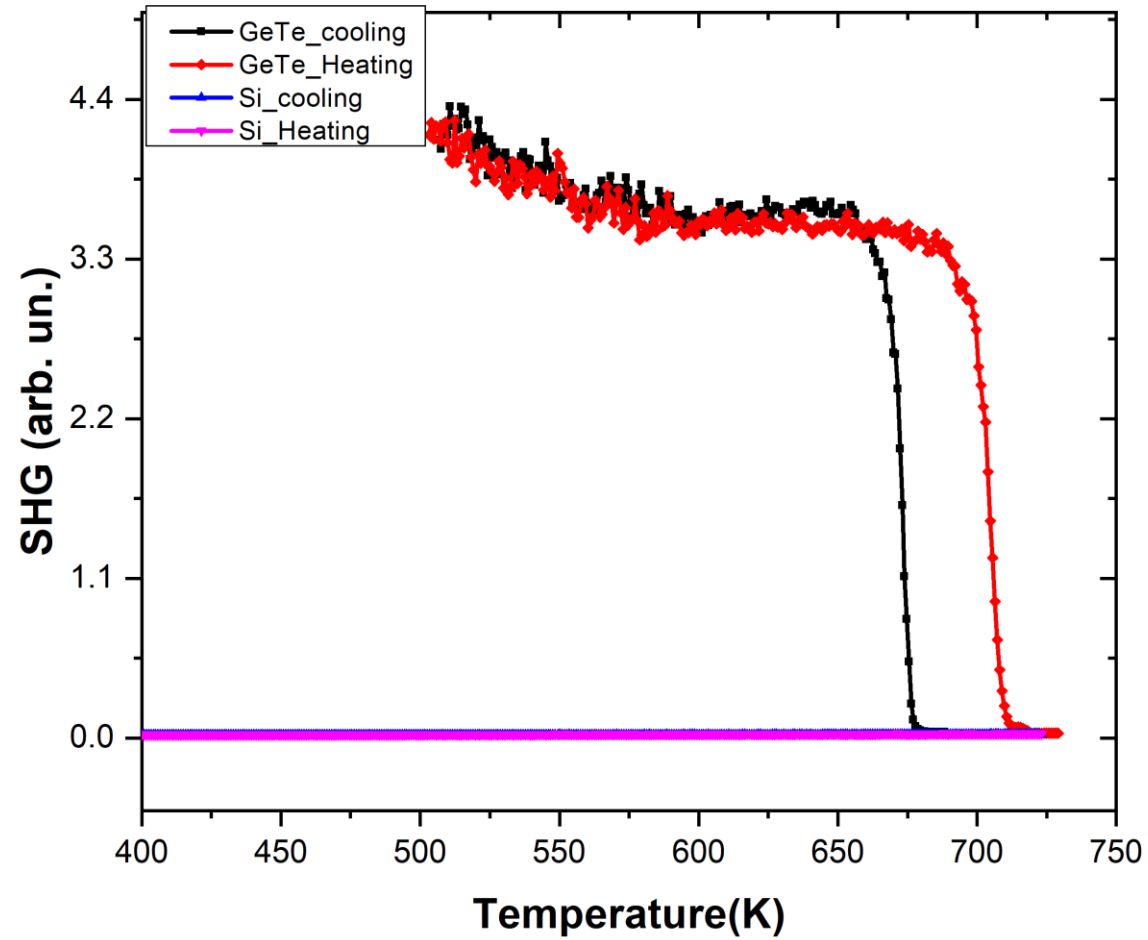
# Results



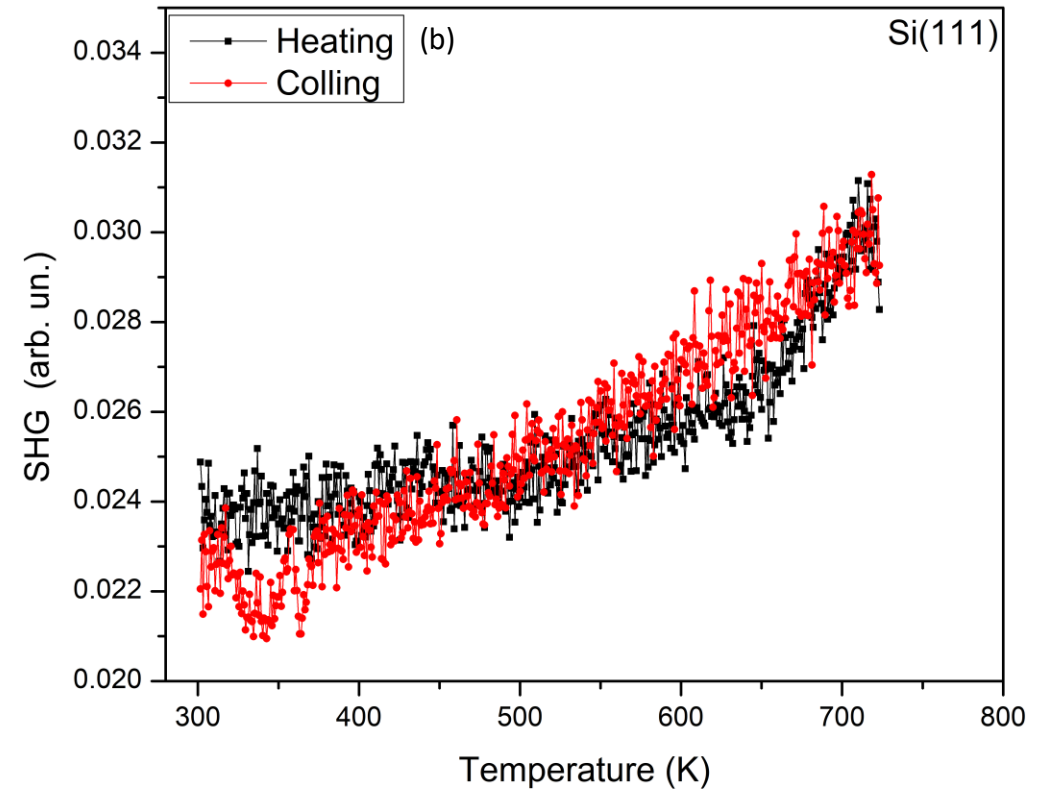
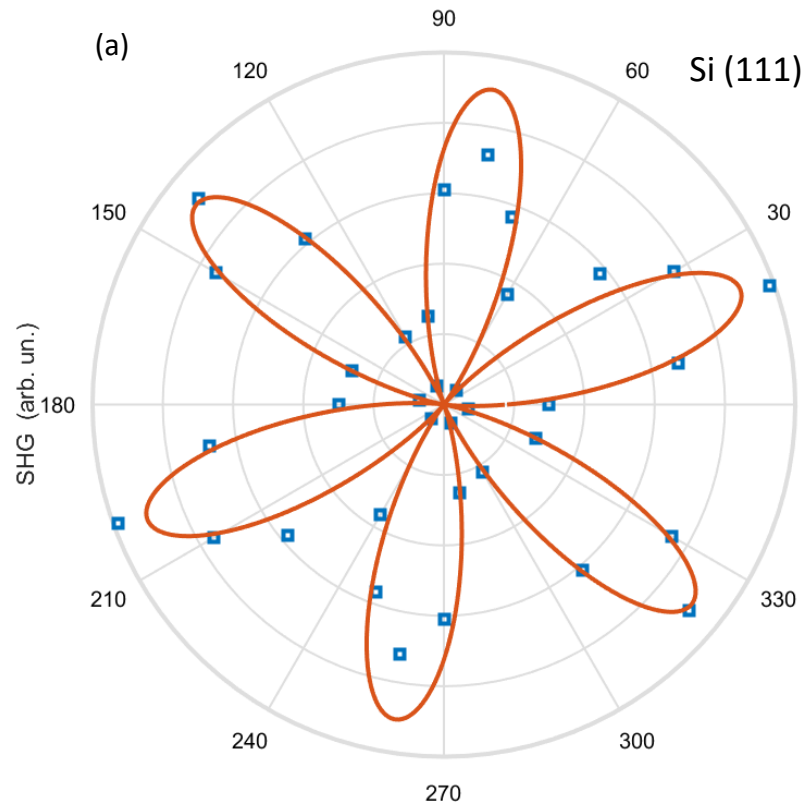
# SHG Results



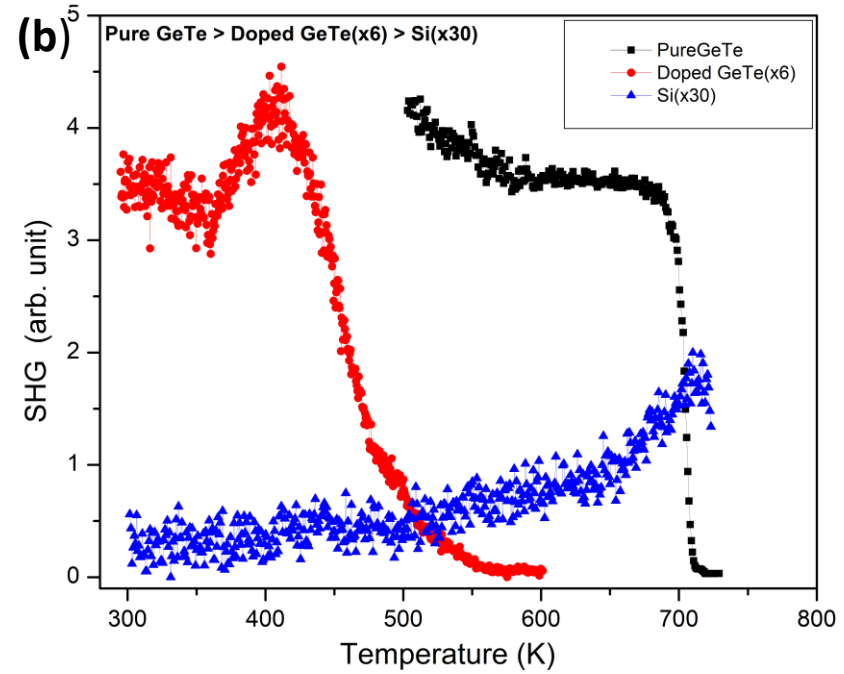
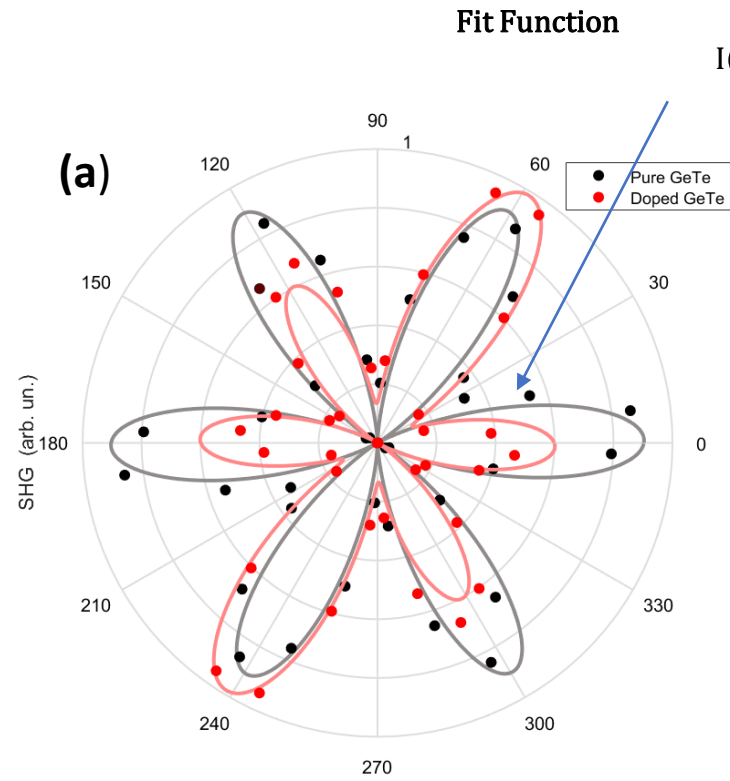
# Temperature scans of pure GeTe and Silicon



# Results



# Results



**Note :** For doped GeTe, the fitting function we used is

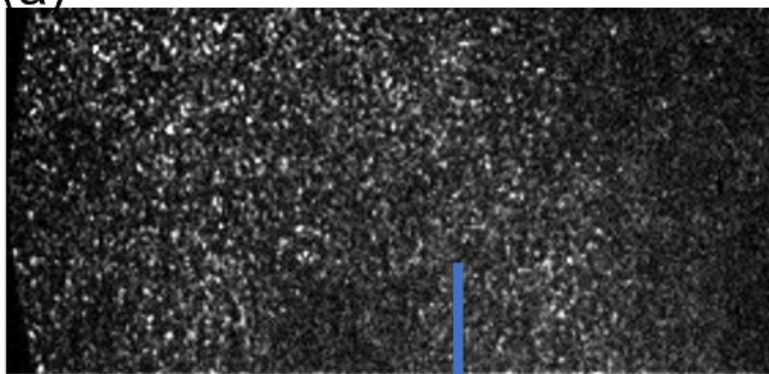
$$I(2\omega) \propto 1/4 A (\cos 3\phi) + B \cos(2\beta + \phi))^2$$

Lukas Mendel, NATURE COMMUNICATIONS | (2018) 9:516.

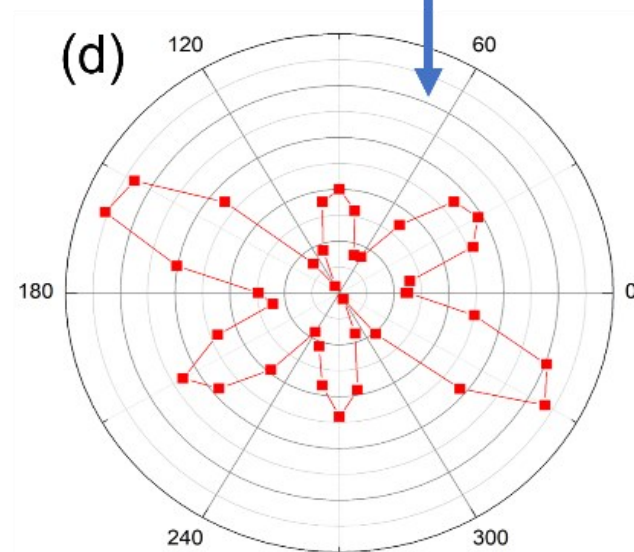
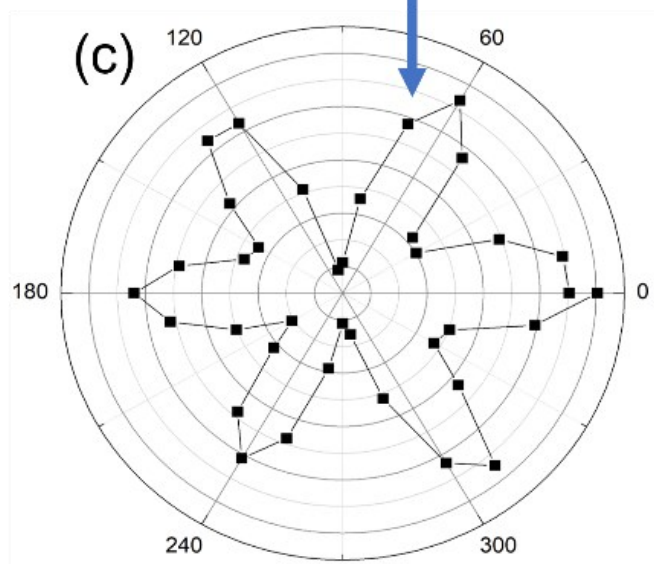
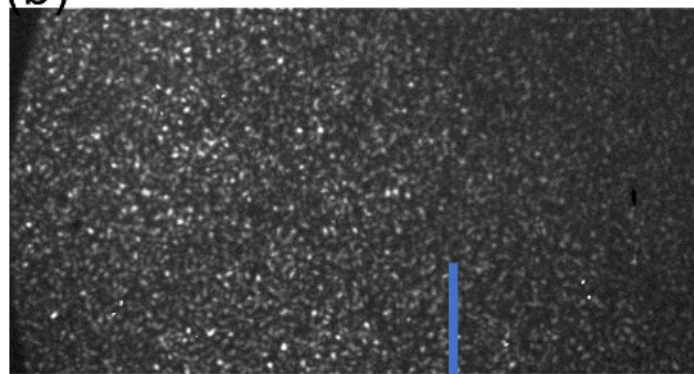


# SHG Imaging

(a) GeTe



(b) SnGeTe



## Conclusion I

- It is confirmed by the SHG that the LSMO coverage has a significant impact on the HZO FE
- PP and SP are the only components which seems to be affected by the FE in HZO, but the mechanism behind it remains to be clarified
- The SHG cannot be solely generated by LSMO but there is an interfacial contribution from HZO/LSMO interface
- We didn't find any symmetry which can fit our data in electric dipole SHG consideration

## Prospective

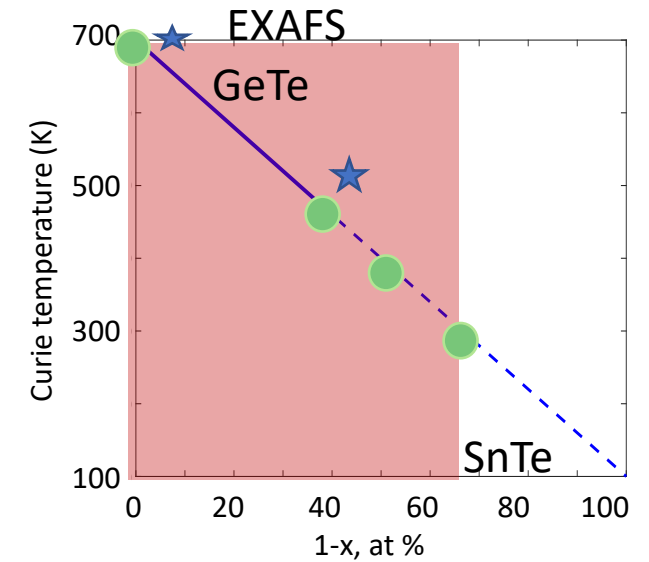
- SHG spectroscopy of HZO samples at higher frequency ?
- SHG Imaging.
- Magnetic measurements.
- High temperature scans.

## Conclusion II

- We measure the anisotropies at different wavelengths in order to find the maximum signal
- Temperature dependence measurement shows a higher values of phase transition ( $T_c = 710$  K) for undoped films and 505 K for doped films
- SHG imaging on both pure and doped films shows tiny domains (probably nano-domains)
- The Curie temperature increases with the content of Germanium

### Prospects

- *It is also possible to measure SHG image with respect to temperature to see the dependence of domains with time*
- *gating of the ferroelectric semiconductor (switching of the polarization on macroscopic area)*

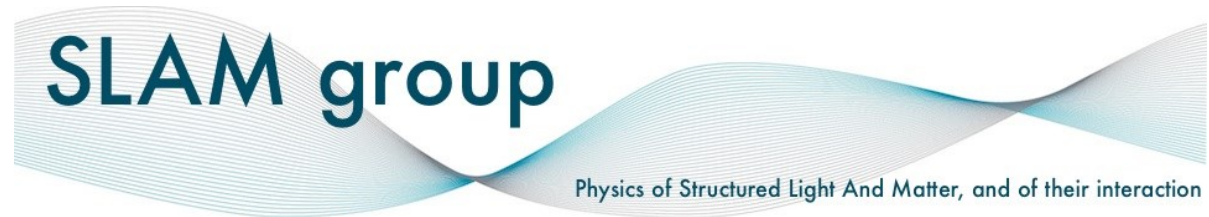


Adapted from A. Lebedev *et al.*,  
*Ferroelectrics*, 298, 189-197 (2004)

## Acknowledgements

### SLAM group

- Prof. Lorenzo Marucci
- Dr. Domenico Paparo
- Dr. Andrea Rubano



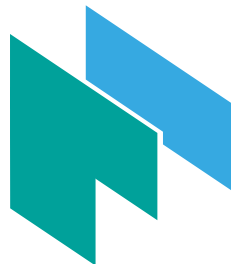
### ETH Zurich

- Prof. Manfred Fiebig
- Dr. Thomas Lottermoser
- Prof. Morgon Trassin



### ICMAB Barcelona. Spain

- Dr. Florencio Sanchez
- Dr. Ignasi Fina



LABORATORY OF  
MULTIFUNCTIONAL THIN FILMS  
AND COMPLEX STRUCTURES

INSTITUT DE CIÈNCIA DE MATERIALS DE BARCELONA, ICMAB-CSIC

Thank You